

PART NUMBER

54LS03BCA-ROCS

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All re-creations are done with the approval of the Original Component Manufacturer. (OCM)

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceeds the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-38535
 - Class Q Military
 - Class V Space Level

Qualified Suppliers List of Distributors (QSLD)

• Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OCM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.



54LS03, 54LS12

Microcircuits, Digital, Bipolar Low-Power Schottky TTL, AND Gates, Monolithic Silicon

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Rochester Electronics Manufactured Components Rochester branded components are	Quality Overview • ISO-9001 • AS9120 certification • Qualified Manufacturers List (QML) MIL-PRF-35835
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FOR REFERENCE ONLY

INCH-POUND MIL-M-38510/300E 7 JANUARY 2003 SUPERSEDING MIL-M-38510/300D 15 JULY 1987

MILITARY SPECIFICATION

MICROCIRCUITS, DIGITAL, BIPOLAR LOW-POWER SCHOTTKY TTL, AND GATES, MONOLITHIC SILICON

Inactive for new design after 18 April 1997.

This specification is approved for use by all Departments and Agencies of the Department of Defense.

1. SCOPE

1.1 <u>Scope.</u> This specification covers the detail requirements for monolithic silicon, low-power Schottky TTL, positive NAND logic gate microcircuits. Two product assurance classes and a choice of case outlines and lead finishes are provided for each type and are reflected in the complete part number. For this product, the requirements of MIL-M-38510 have been superseded by MIL-PRF-38535, (see 6.3).

1.2 Part number. The part number shall be in accordance with MIL-PRF-38535, and as specified herein.

1.2.1 Device types. The device types shall be as follows:

Device type	<u>Circuit</u>
01	Quadruple, 2-input positive NAND gate
02	Quadruple, 2-input positive NAND gate (open collector output)
03	Hex, 1-input inverter gate
04	Hex, 1-input inverter gate (open collector output)
05	Triple, 3-input positive NAND gate
06	Triple, 3-input positive NAND gate (open collector output)
07	Dual, 4-input positive NAND gate
08	Dual, 4-input positive NAND gate (open collector output)
09	Single, 8-input positive NAND gate

1.2.2 Device class. The device class shall be the product assurance level as defined in MIL-PRF-38535.

1.2.3 Case outlines. The case outlines shall be as designated in MIL-STD-1835 and as follows:

Outline letter	Descriptive designator	<u>Terminals</u>	Package style
А	GDFP5-F14 or CDFP6-F14	14	Flat pack
В	GDFP4-14	14	Flat pack
С	GDIP1-T14 or CDIP2-T14	14	Dual-in-line
D	GDFP1-F14 or CDFP2-F14	14	Flat pack
Х	CQCC2-N20	20	Square leadless chip carrier
2	CQCC1-N20	20	Square leadless chip carrier

Beneficial comments (recommendations, additions, deletions) and any pertinent data which may be of use in improving this document should be addressed to: Commander, Defense Supply Center Columbus, ATTN: DSCC-VAS, 3990 East Broad St., Columbus, OH 43216-5000, by using the self addressed Standardization Document Improvement Proposal (DD Form 1426) appearing at the end of this document or by letter.

AMSC N/A <u>DISTRIBUTION STATEMENT A.</u> Approved for public release; distribution is unlimited. FSC 5962

1.3 Absolute maximum ratings.

Supply voltage range Input voltage range	
Storage temperature range	-65° to +150°C
Maximum power dissipation, (P _D) <u>1</u> /	6.1 mW dc
Lead temperature (soldering, 10 seconds)	300°C
Thermal resistance, junction to case (θ_{JC}) :	
Cases A, B, C, D, X, and 2	(See MIL-STD-1835)
Junction temperature (T _J)	175°C <u>2</u> /

1.4 Recommended operating conditions.

Supply voltage (V _{CC})	4.5 V dc minimum to 5.5 V dc
	maximum
Minimum high level input voltage (VIH)	2.0 V
Maximum low level input voltage (VIL)	0.7 V
Case operating temperature range (T _c)	

2. APPLICABLE DOCUMENTS

2.1 Government documents.

2.1.1 <u>Specifications and Standards</u>. The following specifications and standards form a part of this specification to the extent specified herein. Unless otherwise specified, the issues of these documents shall be those listed in the issue of the Departments of Defense Index of Specifications and Standards (DODISS) and supplement thereto, cited in the solicitation.

SPECIFICATION

DEPARTMENT OF DEFENSE

MIL-PRF-38535 - Integrated Circuits (Microcircuits) Manufacturing, General Specification for.

STANDARDS

DEPARTMENT OF DEFENSE

MIL-STD-883	-	Test Method Standard for Microelectronics.
MIL-STD-1835	-	Interface Standard Electronic Component Case Outlines

(Unless otherwise indicated, copies of the above specifications and standards are available from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094.)

2.2 <u>Order of precedence.</u> In the event of a conflict between the text of this specification and the references cited herein, the text of this document takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

 $[\]underline{1}/$ Must withstand the added P_D due to short-circuit test (e.g., $\mathsf{I}_\mathsf{OS}).$

^{2/} Maximum junction temperature (T_J) may be increased during the burn-in screening and steady-state life test. However, such temperatures should not be used under normal operating conditions.

3. REQUIREMENTS

3.1 <u>Qualification</u>. Microcircuits furnished under this specification shall be products that are manufactured by a manufacturer authorized by the qualifying activity for listing on the applicable qualified manufacturers list before contract award (see 4.3 and 6.4).

3.2 <u>Item requirements</u>. The individual item requirements shall be in accordance with MIL-PRF-38535 and as specified herein or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein.

3.3 <u>Design, construction, and physical dimensions.</u> The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535 and herein.

3.3.1 Logic diagrams and terminal connections. The logic diagrams and terminal connections shall be as specified on figure 1.

3.3.2 Truth tables. The truth tables and logic equations shall be as specified on figure 2.

3.3.3 <u>Schematic circuits.</u> The schematic circuits shall be maintained by the manufacturer and made available to the qualifying activity and the preparing activity (DSCC-VAS) upon request.

3.3.4 <u>Case outlines.</u> The case outlines shall be as specified in 1.2.3.

3.4 Lead material and finish. The lead material and finish shall be in accordance with MIL-PRF-38535 (see 6.6).

3.5 <u>Electrical performance characteristics</u>. The electrical performance characteristics are as specified in table I, and apply over the full recommended case operating temperature range, unless otherwise specified.

3.5.1 <u>Post-irradiation performance characteristics</u>. The electrical performance characteristics of radiation hardness assured devices following exposure to the designated radiation levels are as specified in table III, subgroups 1 and 9 and apply at an ambient temperature of +25°C.

3.6 <u>Electrical test requirements.</u> The electrical test requirements for each device class shall be the subgroups specified in table II. The electrical tests for each subgroup are described in table III.

3.7 Marking. Marking shall be in accordance with MIL-PRF-38535.

3.8 <u>Microcircuit group assignment.</u> The devices covered by this specification shall be in microcircuit group number 8 (see MIL-PRF-38535, appendix A).

4. VERIFICATION

4.1 <u>Sampling and inspection</u>. Sampling and inspection procedures shall be in accordance with MIL-PRF-38535 or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not effect the form, fit, or function as described herein.

4.2 <u>Screening</u>. Screening shall be in accordance with MIL-PRF-38535 and shall be conducted on all devices prior to qualification and quality conformance inspection. The following additional criteria shall apply:

- a. The burn-in test duration, test condition, and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The burn-in test circuit shall be maintained under document control by the device manufacturer's Technology Review Board (TRB) in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015 of MIL-STD-883.
- b. Interim and final electrical test parameters shall be as specified in table II, except interim electrical parameters test prior to burn-in is optional at the discretion of the manufacturer.

c. Additional screening for space level product shall be as specified in MIL-PRF-38535, appendix B.

Test	Symbol	Conditions	Device	Limits		Unit
		$-55^{\circ}C \leq T_{C} \leq +125^{\circ}C$	types	Min	Max	
High level output voltage	V _{OH}	$\label{eq:V_CC} \begin{array}{l} V_{CC} = 4.5 \ V, \ V_{IL} = 0.7 \ V; \\ I_{OH} = -400 \ \mu A \end{array}$	01, 03, 05 07, 09	2.5		V
Low level output voltage	V _{OL}	$V_{CC} = 4.5 \text{ V}, I_{OL} = 4 \text{ mA};$ $V_{IH} = 2.0 \text{ V}$	All		0.4	V
Input clamp voltage	V _{IC}	$V_{CC} = 4.5 \text{ V}, \text{ I}_{IN} = -18 \text{ mA};$ $T_{C} = +25^{\circ}\text{C}$	All		-1.5	V
Collector cut-off current	I _{CEX}	$V_{CC} = 4.5 \text{ V}, \text{ V}_{IL} = 0.7 \text{ V};$ $V_{OH} = 5.5 \text{ V}$	02, 04, 06 08		100	μA
High level input current	I _{IH1}	$V_{CC} = 5.5 \text{ V}, \text{ V}_{IN} = 2.7 \text{ V}$	All		20	μΑ
	I _{IH2}	$V_{CC} = 5.5 \text{ V}, \text{ V}_{IN} = 5.5 \text{ V}$	All		100	μA
Low level input current	lıL	$V_{CC} = 5.5 \text{ V}, \text{ V}_{IL} = 0.4 \text{ V}$	01, 02, 03 04, 05, 06	-30	-400	μΑ
			07	-30	-380	
			08	-30	-440	
			09	0	-400	
Short circuit output current	l _{os}	V _{CC} = 5.5 V <u>1</u> /	01, 03, 05 07, 09	-15	-100	mA
High level supply	I _{CCH}	$V_{CC} = 5.5 \text{ V}, \text{ V}_{IN} = 0 \text{ V}$	01, 02		1.6	mA
current			03, 04		2.4	
			05		1.2	
			06		1.4	
			07, 08		0.8	
			09		0.5	
Low level supply	I _{CCL}	$V_{CC} = 5.5 \text{ V}, V_{IN} = 5.5 \text{ V}$	01, 02		4.4	mA
current			03, 04		6.6	
			05, 06		3.3	
			07, 08		2.2	-
			09		1.1	
Propagation delay time high-to-low level	t _{PHL}	$C_{L} = 50 \text{ pF}$ $R_{L} = 2 k\Omega$	01, 03, 05, 07	2	24	ns
		V _{CC} = 5.0 V	02, 04, 06, 08	2	55	
			09	2	38	
Propagation delay time low-to-high level	t _{PLH}	$C_L = 50 \text{ pF}$ $R_L = 2 k\Omega$	01, 03, 05, 07	2	20	ns
		V _{CC} = 5.0 V	02, 04, 06, 08	2	50	
			09	2	32	

TABLE I. Electrical performance characteristics.

 $\underline{1}$ Not more than one output should be shorted at a time.

	Subgroups (see table III)		
MIL-PRF-38535 test requirements	Class S	Class B	
	devices	devices	
Interim electrical parameters	1	1	
Final electrical test parameters	1*, 2, 3, 9, 10, 11	1*, 2, 3, 9	
Group A test requirements	1, 2, 3, 9, 10, 11	1, 2, 3, 9, 10, 11	
Group C end-point electrical parameters	1, 2, 3, 5 9, 10, 11	1, 2, 3	
Group D end-point electrical parameters	1, 2, 3	1, 2, 3	

TABLE II. Electrical test requirements.

*PDA applies to subgroup 1.

4.3 <u>Qualification inspection</u>. Qualification inspection shall be in accordance with MIL-PRF-38535.

4.4 <u>Technology Conformance inspection (TCI)</u>. Technology conformance inspection shall be in accordance with MIL-PRF-38535 and herein for groups A, B, C, and D inspections (see 4.4.1 through 4.4.4).

4.4.1 <u>Group A inspection</u>. Group A inspection shall be in accordance with table III of MIL-PRF-38535 and as follows:

- a. Tests shall be as specified in table II herein.
- b. Subgroups 4, 5, 6, 7, and 8 shall be omitted.

4.4.2 Group B inspection. Group B inspection shall be in accordance with table II MIL-PRF-38535.

4.4.3 <u>Group C inspection</u>. Group C inspection shall be in accordance with table IV of MIL-PRF-38535 and as follows:

- a. End-point electrical parameters shall be as specified in table II herein.
- b. The steady-state life test duration, test condition, and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The burn-in test circuit shall be maintained under document control by the device manufacturer's Technology Review Board (TRB) in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1005 of MIL-STD-883.

4.4.4 <u>Group D inspection</u>. Group D inspection shall be in accordance with table V of MIL-PRF-38535. End-point electrical parameters shall be as specified in table II herein.

4.5 <u>Methods of inspection</u>. Methods of inspection shall be specified and as follows:

4.5.1 <u>Voltage and current.</u> All voltages given are referenced to the microcircuit ground terminal. Currents given are conventional and positive when flowing into the referenced terminal.

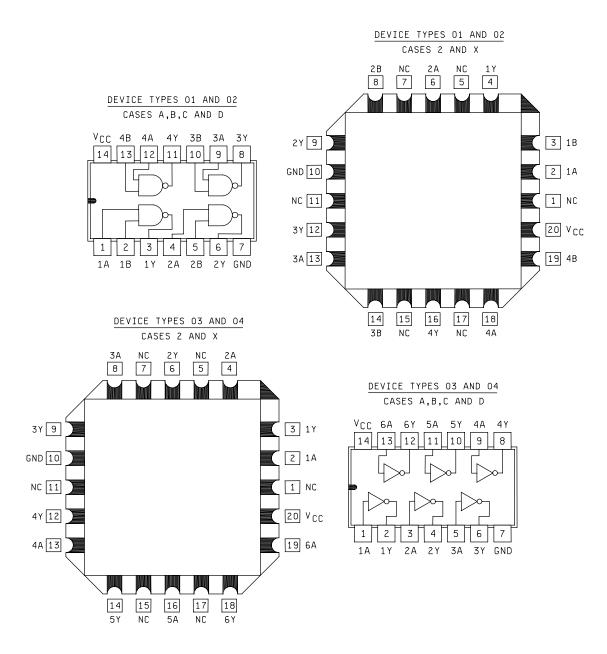


FIGURE 1. Logic diagrams and terminal connections (top view).

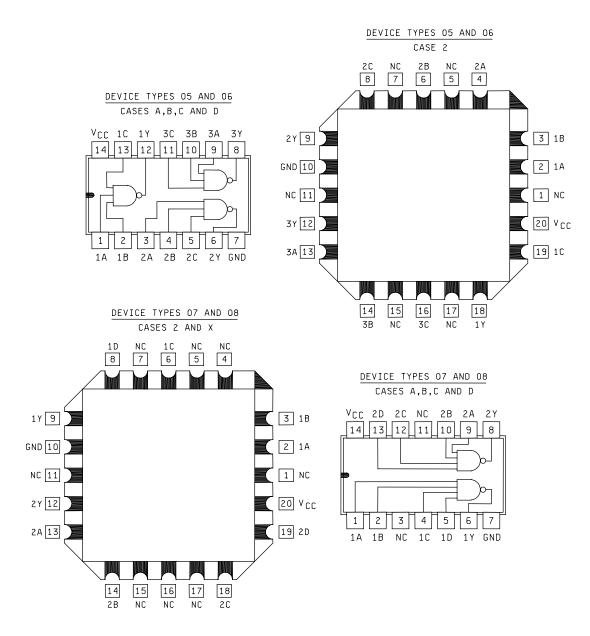


FIGURE 1. Logic diagrams and terminal connections (top view) - Continued.

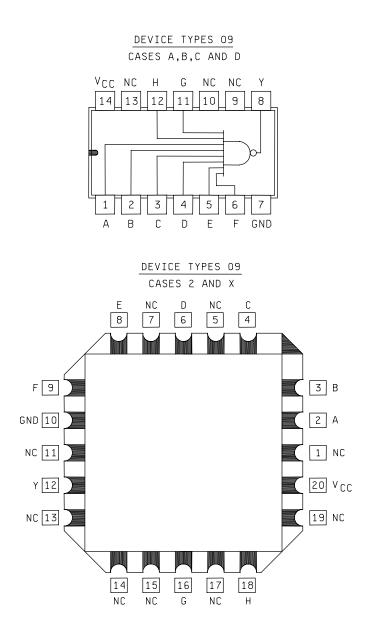


FIGURE 1. Logic diagrams and terminal connections (top view) - Continued.

Device types 01 and 02

Truth table each gate				
Inpu	ut	Output		
Α	В	Y		
L	L	Н		
Н	L	Н		
L	Н	Н		
Н	Н	L		

Positive logic Y = \overline{AB}

Device types 05 and 06

Truth table each gate				
Input			Output	
Α	В	С	Y	
L	L	L	Н	
Н	L	L	Н	
L	Н	L	Н	
Н	Н	L	Н	
L	L	Н	Н	
Н	L	Н	Н	
L	Н	Н	Н	
Н	Н	Н	L	

Positive logic Y = \overline{ABC}

Device types 03 and 04

Truth table each gate			
Input Output			
А	Y		
L H			
Н	L		

Positive logic Y = \overline{A}

Device types 07 and 08

Truth table each gate				
	Output			
Α	В	С	D	Y
L	L	L	L	Н
Н	L	L	L	Н
L	Н	L	L	Н
Н	Н	L	L	Н
L	L	Н	L	Н
Н	L	Н	L	Н
L	Н	Н	L	Н
Н	Н	Н	L	Н
L	L	L	Н	Н
Н	L	L	Н	Н
L	Н	L	Н	Н
Н	Н	L	Н	Н
L	L	Н	Н	Н
Н	L	Н	Н	н
L	Н	Н	Н	Н
Н	Н	Н	Н	L

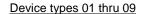
Positive logic Y = \overline{ABCD}

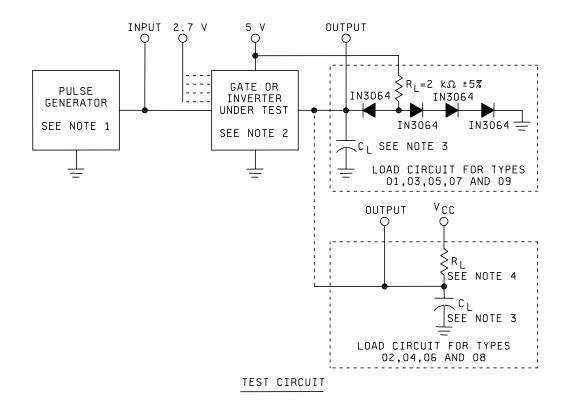
Device type 09

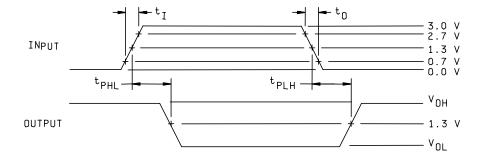
				Truth ta	able									
			In	outs				Output						
А	A B C D E F G H Y													
Н	Н	Н	Н	Н	Н	Н	Н	L						
All of	ther co	mbina	tions of	f H and	L at th	e input	s							
give	e H out	tput.												

Positive logic $Y = \overline{ABCDEFGH}$

FIGURE 2. Truth table and logic equations.







NOTES:

- 1. The pulse generator has the following characteristics:
 - $t_1 \le 15$ ns, $t_0 \le 6$ ns, PRR ≤ 1 MHz, duty cycle = 50% and $Z_{OUT} = 50\Omega$.
- 2. Inputs not under test are at 2.7 V.
- 3. $C_L = 50 \text{ pF} \pm 10\%$, including scope probe, wiring, and stray capacitance.
- 4. $R_L = 2 k\Omega \pm 5\%$.
- 5. Voltage measurements are to be made with respect to network ground terminal.

FIGURE 3. Switching time test circuit and waveforms for device types 01 through 09.

						minal cor	nditions ((pins not		ted may	be high 2	≥2.0 V o	or low ≤ 0).7 V or c							
		MIL-STD-	Cases A,B,C,D	1	2	3	4	5	6	7	8	9	10	11	12	13	14				
Subgroup	Symbol	883 method	Case <u>1/</u> X and 2	2	3	4	6	8	9	10	12	13	14	16	18	19	20	Measured terminal	Lin	its	Unit
		method	Test no.	1A	1B	1Y	2A	2B	2Y	GND	3Y	ЗA	3B	4Y	4A	4B	V _{cc}	terminar	Min	Max	
1	V _{OH}	3006	1	5.5 V	0.7 V	-400 μA	5.5 V	5.5 V	21	GND	51	5.5 V	5.5 V	41	5.5 V	5.5 V	4.5 V	1Y	2.5	IVIAA	V
Tc = 25°C	• OH	"	2	0.0 V	5.5 V	-400 μΛ	"	5.5 V		"		"	"		"	"	"	1Y	-2.0		"
10 = 25 0			3	5.5 V	5.5 V	-400 μA	"	0.7 V	-400 μA	"		"	"		"	"	"	2Y	"		"
			4	3.3 V	"		0.7 V	5.5 V	-400 μA -400 μA	"		"	"			"	"	21 2Y	"		"
			5	"	"		5.5 V	3.3 V	-400 μA	"	-400 μA	"	0.7 V			"	"	21 3Y	"		"
			6	"	"		5.5 V	"		"		0.7 V	5.5 V		"		"	31 3Y	"		"
			7	"	"		"	"		"	-400 μA	0.7 V 5.5 V	5.5 V	400 4	"	0.7 V	"	4Y	"		"
				"			"	"		"			"	-400 μA	071/			41 4Y	"		"
	V	2007	8	2.0.1/	2.0.1/	4 mm A	CNID	CNID		"		5.5 V		-400 μA	0.7 V	5.5 V		4 f 1Y		0.4	"
	V _{OL}	3007	9 10	2.0 V	2.0 V GND	4 mA	GND	GND	4mA	"		GND GND	GND GND		GND "	GND		2Y		0.4	
			10	GND "	GND "		2.0 V GND	2.0 V GND	4MA	"	4 mA	2.0 V	2.0 V			"	"	2 Y 3Y		"	"
			12	"	"		GND	GND		"	4 MA	GND	GND	4 mA	2.0 V	2.0 V	"	4Y			"
	V _{IC}		12	-18 mA			GND	GND	<u> </u>	"		GND	GND	4 IIIA	2.0 V	2.0 V	"	4 f 1A		-1.5	"
	VIC VIC		14	-10 IIIA	-18 mA					"							"	1B		-1.5	"
			14		-10 117		-18 mA			"							"	2A		"	"
			16				-10 IIIA	-18mA		"							"	2B		"	"
			17					1011/1		"		-18 mA					"	3A			"
			18							"		10 11/1	-18 mA				"	3B		"	"
			10							"			10 11/1		-18 mA		"	4A		"	"
			20							"						-18 mA	"	4B		"	"
	I _{IH1}	3010	21	2.7 V	GND		GND	GND		"		GND	GND		GND	GND	5.5 V	1A		20	μA
			22	GND	2.7 V		GND	"		66		"	"		"	"	"	1B		"	"
			23	"	GND		2.7 V	"		"		"	"		"	"	"	2A		"	"
			24	"	"		GND	2.7 V		"		"	"		-	"	"	2B		-	"
			25	"	"		"	GND		"		2.7 V	"		"	"	"	ЗA		"	"
			26		"		"	"		"		GND	2.7 V		=	"	"	3B		=	"
			27	-	"		"	"		"		"	GND		2.7 V	"	"	4A		-	"
			28	"	"		"	"		"		"	"		GND	2.7 V	"	4B			"
	I _{IH2}	"	29	5.5 V	"		"			"		"	=		=	GND	"	1A		100	"
			30	GND	5.5 V		"	"		"		"	=		=	"	"	1B		=	"
			31	-	GND		5.5 V	"		"		"	-		=	"	"	2A		=	"
		"	32	"	"		GND	5.5 V		"		"	"		"	"	"	2B			"
		"	33	"	"		"	GND		"		5.5 V	"		"	"	"	3A			"
			34	"	"		"	"	ļ	"		GND	5.5 V			"		3B			
			35	"	"		"	"	ļ	"		"	GND		5.5 V	"		4A			"
			36	"			"	"	ļ	"		"	GND		GND	5.5 V		4B			
	l _{IL}	3009	37	0.4 V	5.5 V		5.5 V	5.5 V	ļ	"	ļ	5.5 V	5.5 V		5.5 V		"	1A	<u>2</u> /	<u>2</u> /	"
			38	5.5 V	0.4 V		5.5 V		<u> </u>	"		"				"		1B		-	
			39		5.5 V		0.4 V	"	ļ	"			"					2A			
			40	"	"		5.5 V	0.4 V	ļ	"								2B			
			41		"		"	5.5 V	ļ	"		0.4 V						3A		-	
			42						<u> </u>	"		5.5 V	0.4 V					3B			
			43						<u> </u>	"			5.5 V		0.4 V	0.4.1/		4A			
			44				.,		<u> </u>	"					5.5 V	0.4 V		4B 1Y		2/	
	los	3011	45	GND	GND	GND	CND	CNID	CNID		-								<u>3/</u>	<u>3/</u>	mA "
			46 47				GND	GND	GND	"	GND	GND	GND					2Y 3Y			
			47						<u> </u>	"	GND	GIND	GND	GND	GND	GND	"	3Y 4Y	"		"
L			40		I			l	ļ		I			GIND	GND	GND	I	41			

TABLE III. <u>Group A inspection for device type 01</u>. Terminal conditions (pins not designated may be high ≥ 2.0 V or low ≤ 0.7 V or open).

See footnotes at end of device type 01

					Term	ninal con	ditions (p	oins not o	designat	ed may b	be high ≥	: 2.0 V oi	r low ≤ 0 .	7 V or op	pen).						
		MIL-STD-	Cases A,B,C,D	1	2	3	4	5	6	7	8	9	10	11	12	13	14				
Subgroup	Symbol	883 method	Case <u>1</u> / X and 2	2	3	4	6	8	9	10	12	13	14	16	18	19	20	Measured terminal	Lin	nits	Unit
			Test no.	1A	1B	1Y	2A	2B	2Y	GND	3Y	ЗA	3B	4Y	4A	4B	Vcc		Min	Max	
1	Іссн	3005	49	GND	GND		GND	GND		GND		GND	GND		GND	GND	5.5 V	Vcc		1.6	mA
Tc = 25°C	I _{CCL}	3005	50	5.5 V	5.5 V		5.5 V	5.5 V		"		5.5 V	5.5 V		5.5 V	5.5 V	5.5 V	Vcc		4.4	"
2	Same tes	sts, terminal o	conditions a	nd limits a	s for subg	roup 1, ex	cept T _c =	125° C, a	and V _{IC} te	ests are or	nitted.										
3	Same tes	sts, terminal o	conditions a	nd limits a	s for subg	roup 1, ex	cept T _c =	-55° C, a	and V _{IC} te	ests are o	mitted.										
9	t _{PHL}	3003	51	IN	2.7 V	OUT	2.7 V	2.7 V		GND		2.7 V	2.7 V		2.7 V	2.7 V	5.0 V	1A to 1Y	2	17	ns
Tc = 25°C		Fig. 3	52	2.7 V	IN	OUT	2.7 V	-		"		"	"		"	"	**	1B to 1Y	"	"	"
		"	53	"	2.7 V		IN	"	OUT	"		"	"		"	"	"	2A to 2Y	"	"	"
			54	"	"		2.7 V	IN	OUT	"		"	"		"	"	"	2B to 2Y	**	"	"
			55	"	"		"	2.7 V		"	OUT	IN	"		"	"	**	3A to 3Y	**	"	"
			56	"	-		"	-		"	OUT	2.7 V	IN		"	"	**	3B to 3Y	**	"	"
			57	"	=		"	=		"		"	2.7 V	OUT	IN	"	**	4A to 4Y	66	"	"
			58	"	-		"	-		"		"	"	OUT	2.7 V	IN	**	4B to 4Y	**	"	"
	t _{PLH}	"	59	IN	=	OUT	"	=		"		"	"		"	2.7 V	**	1A to 1Y	66	15	"
			60	2.7 V	IN	OUT	"	-		"		"	"		"	"	**	1B to 1Y	**	"	"
			61	"	2.7 V		IN	=	OUT	"		"	"		"	"	**	2A to 2Y	66	"	"
			62	"	-		2.7 V	IN	OUT	"		"	"		"	"	**	2B to 2Y	**	"	"
			63	"	"		"	2.7 V		"	OUT	IN	"		"	"	"	3A to 3Y	**	"	"
			64	"	"					"	OUT	2.7 V	IN		"	"	"	3B to 3Y	**	"	"
			65	"	"		"			"		"	2.7 V	OUT	IN	"	"	4A to 4Y	**	"	"
			66	"	"					"		"	"	OUT	2.7 V	IN	"	4B to 4Y	**	"	"
10	t _{PHL}	"	67	IN	2.7 V	OUT				"		"	"		"	2.7 V	"	1A to 1Y	"	24	"
Tc = 125°C			68	2.7 V	IN	OUT	"	"		"		"	"		"	"	"	1B to 1Y	**	"	"
			69	"	2.7 V		IN		OUT	"		"	"		"	"	"	2A to 2Y	**	"	"
		"	70	"	"		2.7 V	IN	OUT	"		"	"		"		"	2B to 2Y	**	"	"
			71	"	-		"	2.7 V		"	OUT	IN	"		"	"	"	3A to 3Y	**	"	"
			72	"			-	-		"	OUT	2.7 V	IN		"	"	"	3B to 3Y	"	"	"
			73	"	=			=		"		"	2.7 V	OUT	IN	"	"	4A to 4Y	**	"	"
		"	74	"	=		-	=		"		"	"	OUT	2.7 V	IN	"	4B to 4Y	**	"	"
	t _{PLH}	"	75	IN	=	OUT	-	=		"		"	"		"	2.7 V	"	1A to 1Y	**	20	"
			76	2.7 V	IN	OUT				"		"	"		"		"	1B to 1Y	**	"	"
			77	"	2.7 V		IN	-	OUT	"		"	"		"	"	"	2A to 2Y	**	"	"
		"	78	"	"		2.7 V	IN	OUT	"		"	"		"	"	"	2B to 2Y	"	"	"
		"	79	"	"		"	2.7 V		"	OUT	IN	"		"	"	"	3A to 3Y	**	"	"
		"	80	"			"			"	OUT	2.7 V	IN		"	"	"	3B to 3Y	"	"	ű
		"	81	"	"		"			"		"	2.7 V	OUT	IN	"	"	4A to 4Y	**	"	"
		"	82	"	"			"		"		"	2.7 V	OUT	2.7 V	IN	"	4B to 4Y	"	"	"
11	Same tes	sts, terminal o	conditions a	nd limits a	s for subg	roup 10, e	except T _C	= -55° C.													

TABLE III. <u>Group A inspection for device type 01</u> – Continued. Terminal conditions (pins not designated may be high ≥ 2.0 V or low ≤ 0.7 V or open).

 $\underline{1}/~$ For case X and 2, pins not referenced are NC. $\underline{2}/~$ I_{IL} limits in μA are as follows:

12

Measured terminal			Min/max lim	its for circuit		
	А	В	С	D	Ш	F
1A, 1B, 2A, 2B,	-120/-360	-30/-300	-150/-360	-160/-400	-150/-380	-100/-340
3A, 3B, 4A, 4B						

3/ Ios limits for circuit C: -20/-100; for circuits A, B, D, E, and F: -15/-100.

		1	1	1						led may						r	1				
		MIL-STD-	Cases A,B,C,D	1	2	3	4	5	6	7	8	9	10	11	12	13	14				
Subgroup	Symbol	883 method	Case <u>1</u> / X and 2	2	3	4	6	8	9	10	12	13	14	16	18	19	20	Measured terminal	Lin	nits	Unit
			Test no.	1A	1B	1Y	2A	2B	2Y	GND	3Y	ЗA	3B	4Y	4A	4B	V _{CC}		Min	Max	i
1	Vol	3007	1	2.0 V	2.0 V	4 mA	GND	GND		GND	01	GND	GND		GND	GND	4.5 V	1Y		0.4	V dc
Tc = 25°C	VOL	"	2	GND	GND	1110 (2.0 V	2.0 V	4 mA	"		GND	GND		"	"	"	2Y		"	"
10 - 20 0			3	"	"		GND	GND		"	4 mA	2.0 V	2.0 V		66	"	"	3Y		"	"
			4	"	"		GND	GND		"	1110 (GND	GND	4 mA	2.0 V	2.0 V	"	4Y		"	"
	ICEX		5	0.7 V	5.5 V	5.5 V	5.5 V	5.5 V		"		5.5 V	5.5 V	11103	5.5 V	5.5 V	"	1Y		100	μA
	ICEX		6	5.5 V	0.0 V	5.5 V	5.5 V	"		"		"	"		"	"	"	1Y		"	"
			7	"	5.5 V	0.0 1	0.7 V	"	5.5 V	"		"	"		"	"	"	2Y		"	"
			8	66	"		5.5 V	0.7 V	5.5 V	"		"	"		"	"	"	2Y		"	"
			9	66	66		"	5.5 V	0.0 1	"	5.5 V	0.7 V	"		"	"	"	3Y		"	"
			10	"	**		**	"		"	5.5 V	5.5 V	0.7 V		"	"	"	3Y		"	"
			11	"	"		"	"		"		"	5.5 V	5.5 V	0.7 V	"	"	4Y		"	"
			12	"	"		"	"		"		"	5.5 V	5.5 V	5.5 V	0.7 V	"	4Y		"	"
	VIC		13	-18 mA						"							"	1A		-1.5 V	V
			14		-18 mA					"							"	1B		"	"
			15				-18 mA			"							"	2A		"	"
			16					-18 mA		"							"	2B		"	"
			17							"		-18 mA					"	3A		"	"
			18							"			-18 mA				**	3B		"	"
			19							"					-18 mA		"	4A		-	-
			20							"						-18 mA	"	4B		"	"
	I _{IH1}	3010	21	2.7 V	GND		GND	GND		"		GND	GND		GND	GND	5.5 V	1A		20	μΑ
		"	22	GND	2.7 V		GND	**		**		"	"		"	"	**	1B		"	"
		"	23	"	GND		2.7 V	"		"		"	ű		"	"	"	2A		"	ű
		"	24	**	"		GND	2.7 V		"		"	ű			"	"	2B		"	"
		"	25	**	"		"	GND		"		2.7 V	"		"	"	**	3A		"	"
		"	26	"	"		"	"		"		GND	2.7 V		"	"	"	3B		"	"
		"	27	"	"		"	"		"		"	GND		2.7 V	"	"	4A		"	"
		"	28	66	66		"	"		"		-	-		GND	2.7 V	**	4B		"	"
	I _{1 H 2}	"	29	5.5 V	"		"	"		"		"	"		"	GND	"	1A		100	"
			30	GND	5.5 V		"	"		"		"	"			"	"	1B		"	"
			31	"	GND "		5.5 V	"		"		"	"			-	"	2A		"	"
			32	66 66	"		GND	5.5 V		"		"	"			"	"	2B		"	"
			33					GND		"		5.5 V	"					3A			"
			34	**	**		"	"		"		GND	5.5 V			"	"	3B		"	"
			35	"	"		"			"			GND		5.5 V		"	4A		"	"
			36										GND		GND	5.5 V		4B	~		
	I _{I L}	3009	37	0.4 V	5.5 V		5.5 V	5.5 V "		"		5.5 V	5.5 V "		5.5 V		"	1A	<u>2/</u>	<u>2</u> / "	"
			38 39	5.5 V "	0.4 V 5.5 V		5.5 V	"		"			"				"	1B 2A	"	"	"
			<u> </u>	66	5.5 V "		0.4 V	0.4 V		"		66	"		"		"	2A 2B	"	"	"
			40	66	66		5.5 V	0.4 V 5.5 V		"		0.4 V	"				"	2B 3A	"	"	"
			41	66	66			0.0 V		"		0.4 V 5.5 V	0.4 V		"		"	3A 3B	"	"	"
			42	66	66		"	"		"		5.5 V	0.4 V 5.5 V		0.4 V		"	3B 4A	"	"	"
			43	"	"		"	"		"		"	5.5 V		0.4 V 5.5 V		"	4A 4B	"	"	"
			44												5.5 V	0.4 V		4B			

TABLE III. Group A inspection for device type 02. Terminal conditions (pins not designated may be high ≥ 2.0 V or low ≤ 0.7 V or open).

See footnotes at end of device type 02

					Ierr	minai col	naitions	pins not	designa	ted may	be high i	$\geq 2.0 \ V \ C$	or low ≤ 0	0.7 V Or C	ppen).						
		MIL-STD-	Cases A,B,C,D	1	2	3	4	5	6	7	8	9	10	11	12	13	14				
Subgroup	Symbol	-	Case <u>1</u> / X and 2	2	3	4	6	8	9	10	12	13	14	16	18	19	20	Measured terminal	Lim	nits	Unit
		motriou	Test no.	1A	1B	1Y	2A	2B	2Y	GND	3Y	ЗA	3B	4Y	4A	4B	Vcc		Min	Max	
1	ICCL	3005	45	5.5 V	5.5 V		5.5 V	5.5 V		GND		5.5 V	5.5 V		5.5 V	5.5 V	5.5 V	Vcc		4.4	mA
Tc = 25°C	І _{ссн}	3005	46	GND	GND		GND	GND		GND		GND	GND		GND	GND	5.5 V	Vcc		1.6	mA
2	Same te	ests, terminal	conditions a	and limits a	as for sub	group 1, e	except T _C	= 125° C,	and V _{IC}	tests are o	omitted.										
3	Same te	ests, terminal	conditions a	and limits a	as for sub	group 1, e	except T _C	= -55° C,	and V _{IC}	tests are o	omitted.										
9	t _{PHL}	3003	47	IN	2.7 V	OUT	2.7 V	2.7 V		GND		2.7 V	2.7 V		2.7 V	2.7 V	5.0 V	1A to 1Y	2	36	ns
Tc = 25°C		Fig. 3	48	2.7 V	IN	OUT	2.7 V	"		**		"	"			"	"	1B to 1Y	"	"	"
			49	"	2.7 V		IN	-	OUT	"		"	"			"	"	2A to 2Y	**	"	"
			50	"	"		2.7 V	IN	OUT	"		"	"			"	"	2B to 2Y	"	"	"
			51	"	"		"	2.7 V		"	OUT	IN			"	"	"	3A to 3Y	**	"	"
			52	"	"			"		"	OUT	2.7 V	IN			"	"	3B to 3Y	55	"	"
			53	"	"		"	"		"		"	2.7 V	OUT	IN	"	"	4A to 4Y	**	"	"
			54	"	"		"	"		"		"	"	OUT	2.7 V	IN	"	4B to 4Y	**	"	"
	t _{PLH}	"	55	IN	"	OUT	"	=		"		"	"		=	2.7 V	"	1A to 1Y	55	40	"
			56	2.7 V	IN	OUT	"	=		"		"	"		=	"	"	1B to 1Y	"	"	"
			57	"	2.7 V		IN	"	OUT	"		"	"		"	"	"	2A to 2Y	"	"	"
			58	"	"		2.7 V	IN	OUT	"		"	"			"	"	2B to 2Y	**	"	"
			59	"	"		"	2.7 V		"	OUT	IN	"		=	"	"	3A to 3Y	"	"	"
			60	"	"		"	"		"	OUT	2.7 V	IN		"	"	"	3B to 3Y	"	"	"
			61	"	"		"	-		"		"	2.7 V	OUT	IN	"	"	4A to 4Y	**	"	"
			62	"	"		"	-		"		"	"	OUT	2.7 V	IN	"	4B to 4Y	**	"	"
10	t _{PHL}		63	IN	"	OUT	"	"		"		"	"		"	2.7 V	"	1A to 1Y	"	55	"
Tc = 125°C			64	2.7 V	IN	OUT	"	-		"		"	"		=	"	"	1B to 1Y	**	"	"
		"	65	"	2.7 V		IN	"	OUT	"		"	"			"	"	2A to 2Y	**	"	"
			66	"	"		2.7 V	IN	OUT	"		"	"		=	"	"	2B to 2Y	**	"	"
			67	"	"		"	2.7 V		"	OUT	IN	"		=	"	"	3A to 3Y	55	"	"
			68	"	"		"	-		"	OUT	2.7 V	IN		=	"	"	3B to 3Y	**	"	"
			69	"	"		"	"		"		"	2.7 V	OUT	IN	"	"	4A to 4Y	**	"	"
			70	"	"		"	-		"		"	"	OUT	2.7 V	IN	"	4B to 4Y	**	"	"
	t _{PLH}		71	IN	"	OUT	"	"		"		"	"		"	2.7 V	"	1A to 1Y	"	60	"
		"	72	2.7 V	IN	OUT	"	"		"		"	"			"	"	1B to 1Y	**	"	"
		"	73	"	2.7 V		IN	"	OUT	"		"	"		"	"	"	2A to 2Y	"	"	"
		"	74	"	"		2.7 V	IN	OUT	"		"	"		"	"	"	2B to 2Y	"	"	"
		"	75	"	"		"	2.7 V		"	OUT	IN	"			"	"	3A to 3Y	"	"	"
		"	76	"	"		"	"		"	OUT	2.7 V	IN			"	"	3B to 3Y	**	"	"
		"	77	"	"		"	"		"		"	2.7 V	OUT	IN	"	"	4A to 4Y	"	"	"
		"	78	"	"		"	"		"		"	2.7 V	OUT	2.7 V	IN	"	4B to 4Y	"	"	"
11	Same te	ests, terminal	conditions a	and limits a	as for sub	group 10.	except To	; = -55° C													

TABLE III. <u>Group A inspection for device type 02</u> – Continued. Terminal conditions (pins not designated may be high ≥ 2.0 V or low ≤ 0.7 V or open).

 $\underline{1}/~$ For case X and 2, pins not referenced are NC. $\underline{2}/~$ I_{IL} limits in μA are as follows:

Measured terminal			Min/max lim	its for circuit		
	А	В	С	D	Ш	F
1A, 1B, 2A, 2B,	-160/-400	-30/-300	-150/-380	-160/-400	-150/-380	-100/-340
3A, 3B, 4A, 4B						

					lerr	minal coi	nditions	(pins not	designa	ted may	be high	≥2.0 V c	or low ≤ 0).7 V or c	pen).						
		MIL-STD-	Cases A,B,C,D	1	2	3	4	5	6	7	8	9	10	11	12	13	14				
Subgroup	Symbol	883 method	Case <u>1</u> / X and 2	2	3	4	6	8	9	10	12	13	14	16	18	19	20	Measured terminal	Lin	nits	Unit
			Test no.	1A	1Y	2A	2Y	3A	3Y	GND	4Y	4A	5Y	5A	6Y	6A	V _{CC}		Min	Max	
1	V _{он}	3006	1	0.7 V	-400 μA	5.5 V		5.5 V		GND		5.5 V		5.5 V		5.5 V	4.5 V	1Y	2.5		V
Tc = 25°C			2	5.5 V		0.7 V	-400 μA	5.5 V		"		"		"		"	"	2Y	"		"
			3	"		5.5 V		0.7 V	-400 μA	"		"		"		"	"	3Y	=		"
			4	"		-		5.5 V		"	-400 μA	0.7 V		"		"	"	4Y	=		"
			5	**		-		"		"		5.5 V	-400 µA	0.7 V		"	"	5Y	=		"
			6	"		н		"		"		5.5 V		5.5 V	-400 μA	0.7 V	"	6Y	"		u
	Vol	3007	7	2.0 V	4 mA	GND		GND		"		GND		GND		GND	"	1Y		0.4	"
	01		8	GND		2.0 V	4 mA	GND		"		"		"		"	**	2Y		"	"
			9	**		GND		2.0 V	4 mA	"		"		"		"	**	3Y		"	"
			10	**		=		GND		"	4 mA	2.0 V		"		"	"	4Y		"	"
			11	"		=		"		"		GND	4 mA	2.0 V		"	"	5Y		"	"
			12	-		"		"		"		GND		GND	4 mA	2.0 V	66	6Y		"	"
	VIC		13	-18 mA						"							"	1A		-1.5	"
			14			-18 mA				"							"	2A		"	"
			15					-18 mA		"							"	ЗA		"	"
			16							"		-18 mA					"	4A		"	"
			17							"				-18 mA			"	5A		"	"
			18							"						-18 mA	**	6A		"	"
	$I_{\rm H1}$	3010	19	2.7 V		GND		GND		"		GND		GND		GND	5.5 V	1A		20	μΑ
			20	GND		2.7 V		GND		"		"		"		"	"	2A		"	"
			21	"		GND		2.7 V		"		"		"		"	"	ЗA		"	"
			22	"				GND		"		2.7 V		"		"	"	4A		"	"
			23	**		"		"				GND		2.7 V				5A		"	"
			24					"		"		"		GND		2.7 V	"	6A			"
	I _{1 H 2}		25	5.5 V				"		"		"				GND	"	1A		100	"
			26 27	GND		5.5 V				"		"					"	2A 3A			"
			27	"		GND "		5.5 V GND		"		5.5 V				"	"	3A 4A		"	"
			28	66				GND "		"		S.S V GND		5.5 V		"	66	4A 5A		"	"
			<u>29</u> 30	"				"		"		GND		GND		5.5 V	"	5A 6A		"	"
	կլ	3009	30	0.4 V		5.5 V		5.5 V		"		5.5 V		5.5 V		3.3 V	"	1A	2/	2/	"
	4 L	5005	32	5.5 V		0.4 V		5.5 V		"		0.0 V		J.J V "		"	66	2A	<u>/</u>	"	"
			33			5.5 V		0.4 V		"		"		"		"	**	3A	"	"	"
			34	"		0.0 v "		5.5 V		"		0.4 V		"		"	"	4A	"	"	"
			35	"		"		"		"		5.5 V		0.4 V		"	"	5A	"	"	"
			36	"		н		"		"	<u> </u>	5.5 V		5.5 V		0.4 V	"	6A	"	"	"
	los	3011	37	GND	GND			"		"							"	1Y	3/	3/	mA
			38			GND	GND			"							"	2Y	"	"	"
			39					GND	GND	"							"	3Y	"	"	"
			40					İ	l	"	GND	GND				l	"	4Y	"	"	"
			41						1	"			GND	GND			**	5Y	"	"	"
			42							"					GND	GND	**	6Y	"	"	"

TABLE III. <u>Group A inspection for device type 03</u>. Terminal conditions (pins not designated may be high ≥ 2.0 V or low ≤ 0.7 V or open).

See footnotes at end of device type 03.

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					1011		landonio		abbigila	leu may	be mgn							r			
		MIL-STD-	Cases A.B.C.D	1	2	3	4	5	6	7	8	9	10	11	12	13	14				
Subgroup	Symbol	883	Case <u>1</u> /	2	3	4	6	8	9	10	12	13	14	16	18	19	20	Measured	Lim	nits	Unit
		method	X and 2															terminal			
			Test no.	1A	1Y	2A	2Y	ЗA	3Y	GND	4Y	4A	5Y	5A	6Y	6A	V _{cc}		Min	Max	
1	Іссн	3005	43	GND		GND		GND		GND		GND		GND		GND	5.5 V	Vcc		2.4	mA
Tc = 25°C	I _{CCL}	3005	44	5,5 V		5.5 V		5.5 V		"		5.5 V		5.5 V		5.5 V	"	Vcc		6.6	"
2	Same te	ests, terminal	conditions a	and limits a	as for sub	group 1, e	except T _C	= 125° C,	and V _{IC}	ests are o	mitted.										
3	Same te	ests, terminal	conditions a	and limits a	as for sub	group 1, e	except T _C	= -55° C,	and V _{IC}	tests are o	omitted.										
9	t _{PHL}	3003	45	IN	OUT	2.7 V		2.7 V		GND		2.7 V		2.7 V		2.7 V	5.0 V	1A to 1Y	2	17	ns
Tc = 25°C		(Fig. 3)	46	2.7 V		IN	OUT	2.7 V		"		"		"		"	**	2A to 2Y	**	"	"
		,	47	"		2.7 V		IN	OUT	"		"		"		"	"	3A to 3Y	"	"	"
			48	"		"		2.7 V		"	OUT	IN		"		"	"	4A to 4Y	"	"	**
			49	"		"		"		"		2.7 V	OUT	IN		"	**	5A to 5Y	"	"	"
			50	"		"		"		"		"		2.7 V	OUT	IN	"	6A to 6Y	"	"	"
	t _{PLH}		51	IN	OUT	"		"		"		"		"		2.7 V	**	1A to 1Y	**	15	"
			52	2.7 V		IN	OUT	"		"		"		"		"	"	2A to 2Y	"	"	"
			53	"		2.7 V		IN	OUT	"		"		"		"	**	3A to 3Y	"	"	"
			54	"		"		2.7 V		"	OUT	IN		"		"	**	4A to 4Y	"	"	"
			55	"		"		"		"		2.7 V	OUT	IN		"	"	5A to 5Y	"	"	"
			56	"		"		"		"		"		2.7 V	OUT	IN	"	6A to 6Y	"	"	**
10	t _{PHL}		57	IN	OUT	н		"		GND		"		"		2.7 V	"	1A to 1Y	"	24	"
Tc = 125°C			58	2.7 V		IN	OUT	"		"		"		"		"	"	2A to 2Y	"	"	"
			59	"		2.7 V		IN	OUT	"		"		"		"	**	3A to 3Y	"	"	"
			60	"		"		2.7 V		"	OUT	IN		"		"	"	4A to 4Y	"	"	"
			61	"		"		"		"		2.7 V	OUT	IN		"	**	5A to 5Y	"	"	"
			62	"		"		"		"		"		2.7 V	OUT	IN	**	6A to 6Y	"	"	"
	t _{PLH}		63	IN	OUT	"		"		"		"		"		2.7 V	**	1A to 1Y	"	20	"
			64	2.7 V		IN	OUT	"		"		"		"		"	"	2A to 2Y	"	"	"
			65	"		2.7 V		IN	OUT	"		"		"		"	"	3A to 3Y	"	"	**
			66	"		"		2.7 V		"	OUT	IN		"		"	"	4A to 4Y	"	"	"
			67	"		"		"		"		2.7 V	OUT	IN		"	**	5A to 5Y	"	"	**
			68	"		"		"		"		2.7 V		2.7 V	OUT	IN	"	6A to 6Y	**	"	"
11	Same te	ests, terminal	conditions a	and limits a	as for sub	group 10.	except T	a = −55° C).												

TABLE III. <u>Group A inspection for device type 03</u> – Continued. Terminal conditions (pins not designated may be high ≥ 2.0 V or low ≤ 0.7 V or open).

 $\underline{1}/~$ For case X and 2, pins not referenced are NC. $\underline{2}/~$ I_{IL} limits in μA are as follows:

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Measured terminal			Min/max lim	its for circuit		
	А	В	С	D	Е	F
1A, 2A, 3A,	-150/-380	-30/-300	-150/-380	-160/-400	-150/-380	-100/-340
4A, 5A, 6A						

 $\underline{3}/~I_{OS}$ limits for circuit C: -20/-100 mA; for circuits A, B, D, E, and F: -15/-100 mA.

						minal cor			<u> </u>		<u> </u>				. /						
		MIL-STD-	Cases A,B,C,D	1	2	3	4	5	6	7	8	9	10	11	12	13	14				
ubgroup	Symbol		Case <u>1</u> / X and 2	2	3	4	6	8	9	10	12	13	14	16	18	19	20	Measured terminal	Lin	nits	Unit
		method	Test no.	1A	1Y	2A	2Y	ЗA	3Y	GND	4Y	4A	5Y	5A	6Y	6A	V _{cc}	terminar	Min	Max	-
1	Vol	3007	1	2.0 V	4 mA	GND	21	GND	01	GND		GND	01	GND	01	GND	4.5 V	1Y		0.4	"
c = 25°C	VOL	"	2	GND	4 11/ 1	2.0 V	4 mA	GND		"		"		"		"	4.0 V	2Y		"	"
0 = 25 0			3	"		GND	4 11/ (2.0 V	4 mA	"		"		"		"	"	3Y		"	"
			4	"		"		GND	4 1117	"	4 mA	2.0 V		"		"	"	4Y		"	"
			5	"		н		"		"	4 1117	GND	4 mA	2.0 V		"	"	5Y		"	"
			6	"		"		"		"		GND	- 11/3	GND	4 mA	2.0 V	"	6Y		"	"
	I _{CEX}		7	0.7 V	5.5 V	5.5 V		5.5 V		"		5.5 V		5.5 V	11103	5.5 V	"	1Y		100	μA
	-CEX		8	5.5 V	0.0 1	0.7 V	5.5 V	5.5 V		"		"		"		"	"	2Y		"	"
			9	"		5.5 V	0.0 1	0.7 V	5.5 V	"		"		"		"	"	3Y		"	"
			10	"		"		5.5 V	0.0 1	"	5.5 V	0.7 V		"		"	"	4Y		"	"
			11	**		н		"		"		5.5 V	5.5 V	0.7 V		"	"	5Y		"	"
			12	**		"		"		"		5.5 V		5.5 V	5.5 V	0.7 V	"	6Y		"	"
	VIC		13	-18 mA						"							"	1A		-1.5	V
			14	-		-18 mA				"							"	2A		"	"
			15					-18 mA		"							"	3A		"	"
			16							"		-18 mA					"	4A		"	"
			17							"				-18 mA			"	5A		"	**
			18							"						-18 mA	"	6A		"	"
	I _{IH1}	3010	19	2.7 V		GND		GND		"		GND		GND		GND	5.5 V	1A		20	μA
			20	GND		2.7 V		GND		"		"		"		"	"	2A		"	"
			21	"		GND		2.7 V		"		"		"		"	"	3A		"	**
		"	22	"		"		GND		"		2.7 V		"		"	"	4A		"	"
		"	23	"		"		"		"		GND		2.7 V		"	"	5A		"	"
		"	24	**		"		**		"		"		GND		2.7 V	**	6A		"	"
	I _{IH2}	"	25	5.5 V		"		"		"		"		"		GND	"	1A		100	"
		"	26	GND		5.5 V		"		"		"		"		"	"	2A		"	"
			27	"		GND		5.5 V		"		"		"		"	"	3A		"	"
		"	28	"		"		GND		"		5.5 V		"		"	"	4A		"	"
		"	29	"		"		"		"		GND		5.5 V		"	"	5A		"	"
		"	30	"		"		"		"		GND		GND		5.5 V	"	6A		"	"
	հե	3009	31	0.4 V		5.5 V		5.5 V		"		5.5 V		5.5 V		5.5 V "	"	1A	<u>2</u> /	<u>2</u> / "	"
			32	5.5 V		0.4 V		5.5 V		"		"		"		"		2A			
			33			5.5 V		0.4 V		"				"				3A			"
			34					5.5 V		"		0.4 V				"		4A			"
			35					"				5.5 V		0.4 V			"	5A			"
			36							"		"		5.5 V		0.4 V	"	6A			
	ICCL	3005	37							"						5.5 V	"	V _{cc}		6.6	mA
	I _{ссн}	3005	38	GND		GND		GND				GND		GND		GND		Vcc		2.4	mA

TABLE III. <u>Group A inspection for device type 04</u>. Terminal conditions (pins not designated may be high ≥ 2.0 V or low ≤ 0.7 V or open).

See footnotes at end of device type 04.

								1-11-11-11-11-11-11-11-11-11-11-11-11-1		tou may	j. i										
		MIL-STD-	Cases A,B,C,D	1	2	3	4	5	6	7	8	9	10	11	12	13	14				
Subgroup	Symbol	883 method	Case <u>1</u> / X and 2	2	3	4	6	8	9	10	12	13	14	16	18	19	20	Measured terminal	Lim	nits	Unit
			Test no.	1A	1Y	2A	2Y	3A	3Y	GND	4Y	4A	5Y	5A	6Y	6A	V _{CC}	1	Min	Max	
9	t _{PHL}	3003	39	IN	OUT	2.7 V		2.7 V		GND		2.7 V		2.7 V		2.7 V	5.0 V	1A to 1Y	2	36	ns
Tc = 25°C		(Fig. 3)	40	2.7 V		IN	OUT	2.7 V		"				"		"	"	2A to 2Y	"	"	"
			41	"		2.7 V		IN	OUT	"		"		"		"	"	3A to 3Y	"	"	"
			42	"		"		"		"	OUT	IN		"		"	"	4A to 4Y	**	"	"
			43	"		"		"		"		2.7 V	OUT	IN		"	"	5A to 5Y	"	"	"
			44	"		"		"		"				2.7 V	OUT	IN	"	6A to 6Y	"	"	"
	t _{PLH}		45	IN	OUT	"		"		"				"		2.7 V	"	1A to 1Y	"	40	"
			46	2.7 V		IN	OUT	"		"				"		"	"	2A to 2Y	"	"	"
			47	"		2.7 V		IN	OUT	"				"		"	"	3A to 3Y	"	"	"
			48	"		"		2.7 V		"	OUT	IN				"	"	4A to 4Y	"	"	"
			49	"		"		"		"		2.7 V	OUT	IN		"	"	5A to 5Y	"	"	"
			50	"		"		"		"				2.7 V	OUT	IN	**	6A to 6Y	"	"	"
10	t _{PHL}		51	IN	OUT	"		"		"				"		2.7 V	"	1A to 1Y	"	55	"
Tc = 125°C			52	2.7 V		IN	OUT	"		"				"		"	**	2A to 2Y	"	"	"
			53	"		2.7 V		IN	OUT	"						"	"	3A to 3Y	"	"	"
			54	"		"		2.7 V		"	OUT	IN		"		"	**	4A to 4Y	"	"	"
			55	"		"		"		"		2.7 V	OUT	IN		"	"	5A to 5Y	"	"	"
			56	"		"		"		"				2.7 V	OUT	IN	**	6A to 6Y	"	"	"
	t _{PLH}		57	IN	OUT	"		"		"				"		2.7 V	"	1A to 1Y	"	60	"
			58	2.7 V		IN	OUT	"		"		"		"		"	"	2A to 2Y	"	"	"
			59	"		2.7 V		IN	OUT	"				"		"	"	3A to 3Y	"	"	"
			60	"		"		2.7 V		"	OUT	IN		"		"	"	4A to 4Y	"	"	"
			61	"		"		"		"		2.7 V	OUT	IN		"	"	5A to 5Y	"	"	"
			62	"		"		"		"		2.7 V		2.7 V	OUT	IN	"	6A to 6Y	"	"	"
11	Same te	ests, terminal	conditions a	and limits a	as for sub	aroup 10.	except T	c = −55° C													

TABLE III. <u>Group A inspection for device type 04</u> – Continued. Terminal conditions (pins not designated may be high ≥ 2.0 V or low ≤ 0.7 V or open).

 $\underline{1}/~$ For case X and 2, pins not referenced are NC. $\underline{2}/~$ I_{IL} limits in μA are as follows:

Measured terminal			Min/max lim	its for circuit		
	А	В	С	D	E	F
1A, 2A, 3A,	-150/-380	-30/-300	-150/-380	-160/-400	-150/-380	-120/-360
4A, 5A, 6A						

						minal coi	nditions	(pins not	designa	ted may	be high 2	≥ 2.0 V c	or low ≤ 0).7 V or o							
		MIL-STD-	Cases A,B,C,D	1	2	3	4	5	6	7	8	9	10	11	12	13	14				
Subgroup	Symbol	883 method	Case <u>1/</u> X and 2	2	3	4	6	8	9	10	12	13	14	16	18	19	20	Measured terminal	Lim	nits	Unit
			Test no.	1A	1B	2A	2B	2C	2Y	GND	3Y	ЗA	3B	3C	1Y	1C	V _{cc}		Min	Max	
1	Vон	3006	1	0.7 V	5.5 V	5.5 V	5.5 V	5.5 V		GND	0.	5.5 V	5.5 V	5.5 V	-400µA	5.5 V	4.5 V	1Y	2.5	max	V
Tc = 25°C	•08	"	2	5.5 V	0.7 V	"	"	"		"		"	"	"	"	5.5 V	"	1Y	"		"
10 = 25 0			3	0.0 V	5.5 V	"	"	"		"		"	"	"	"	0.7 V	"	1Y	"		"
			4	"	5.5 V	0.7 V	"	"	-400µA	"		"		"		5.5 V	"	2Y	**		"
			5	"	"	5.5 V	0.7 V		-400μA "	"		"		"		3.3 V	"	21 2Y	"		"
			6	"	"	5.5 V	5.5 V	0.7 V		"		"		"		"	"	21 2Y	"		"
			6 7	"	"	"	0.5 V	5.5 V		"	4004	0.7 V	"	"			"	2 Y 3Y	"		"
				"	"			5.5 V		"	-400μA			"			"		"		"
			8							"		5.5 V	0.7 V				"	3Y			"
			9							"			5.5 V	0.7 V			"	3Y			"
	Vol	3007	10	2.0 V	2.0 V	GND	GND	GND		"		GND	GND	GND	4 mA	2.0 V		1Y		0.4	"
			11	GND	GND	2.0 V	2.0 V	2.0 V	4 mA	"		GND	GND	GND		GND	"	2Y		"	"
			12	GND	GND	GND	GND	GND		"	4 mA	2.0 V	2.0 V	2.0 V		GND	"	3Y			"
	Vic		13	-18 mA	40 1					"							"	1A		-1.5	"
			14		-18 mA	40 ^											"	1B		"	"
			15			-18 mA	10.1			"							"	2A		"	"
			16				-18 mA	10.1		"							"	2B		"	"
			17					-18 mA		"							"	2C		"	"
			18							"		-18 mA					"	3A		"	"
			19							"			-18 mA				"	3B		"	"
			20							"				-18 mA				3C		"	"
			21													-18 mA	"	1C			
	ILH 1	3010	22	2.7 V	GND	GND	GND	GND		"		GND	GND	GND		GND	5.5 V	1A		20	μΑ
		"	23	GND	2.7 V	"	"	"		"		"	"			GND	"	1B		"	"
			24	"	GND	"	"	"		"		"	"			2.7 V	"	1C		"	"
			25	"		2.7 V	"	"		"		"	"			GND	**	2A		"	"
		"	26	11	"	GND	2.7 V	"		"		"	"			"	"	2B		"	"
		"	27	"	"	"	GND	2.7 V		"		"	=			"	"	2C		"	"
		"	28	"	"	"	"	GND		"		2.7 V				"	"	ЗA		"	"
		"	29	"	"	"	"	"		"		GND	2.7 V			"	"	3B		"	"
			30	"	"	"	"			"		"	GND	2.7 V		"	"	3C			"
	I _{IH2}		31	5.5 V	"	-	"	"		"		-				"		1A		100	
			32	GND	5.5 V	"	"	"		"		"	"	GND		"	"	1B		"	"
		"	33	"	GND	"	"	"		"		"	"			5.5 V	"	1C		"	"
			34	"	"	5.5 V		"		"		"	"			GND	"	2A		"	"
			35	"	"	GND	5.5 V	"		"		"	"			"	"	2B		"	"
		"	36	"	"		GND	5.5 V		"		"				"	"	2C		"	"
		"	37	"	"		"	GND		"		5.5 V	"			"	"	3A		"	"
			38	"	"	"	"	"		"		GND	5.5 V			"	"	3B		"	"
		"	39	"	"	"	"	"		"		"	GND	5.5 V		"	"	3C		"	"
	հե	3009	40	0.4 V	5.5 V	5.5 V	5.5 V	5.5 V		"		5.5 V	5.5 V	"		5.5 V	"	1A	<u>2</u> /	<u>2</u> /	"
			41	5.5 V	0.4 V	"	"	"		"		"	"	"		"	"	1B	"	"	"
		"	42	"	5.5 V	"	"	"		"		"	"	"		0.4 V	"	1C	"	"	"
		"	43	**	"	0.4 V	"			"		"	"	"		5.5 V	"	2A	**	"	"
		"	44	"	"	5.5 V	0.4 V	-		"			"	"			"	2B	"	"	"
		"	45	"	"	"	5.5 V	0.4 V		"		"	"	"		"	"	2C	"	"	"
		"	46	**	"	-	"	5.5 V		"		0.4 V	-	"		"	"	ЗA	**	"	"
		"	47	"	"	-	"	"		"		5.5 V	0.4 V	"		"	"	3B	"	"	"
		"	48	"	"	"	"	"		"		"	5.5 V	0.4 V		"	"	3C	"	"	"

TABLE III. <u>Group A inspection for device type 05</u>. Terminal conditions (pins not designated may be high ≥ 2.0 V or low ≤ 0.7 V or open).

See footnotes at end of device type 05

			-		lerr	ninal cor	nditions	(pins not	designa	ted may	be high	$\geq 2.0 \ V \ C$	or low ≤ 0). / V or c	ppen).	-					
		MIL-STD-	Cases A,B,C,D	1	2	3	4	5	6	7	8	9	10	11	12	13	14				
Subgroup	Symbol	883 method	Case <u>1</u> / X and 2	2	3	4	6	8	9	10	12	13	14	16	18	19	20	Measured terminal	Lin	nits	Unit
		methou	Test no.	1A	1B	2A	2B	2C	2Y	GND	3Y	ЗA	3B	3C	1Y	1C	V _{cc}	terminar	Min	Max	
1	los	3011	49	GND	GND	2/1	20	20	21	GND		0/1	50	50	GND	GND	5.5 V	1Y	3/	3/	mA
Tc = 25°C	105	0011	50	OND	OND	GND	GND	GND	GND	"					OND	OND	"	2Y		"	"
			51							"	GND	GND	GND	GND			"	3Y	66	"	"
	Іссн	3005	52	GND	GND	GND	GND	GND		"	-	GND	GND	GND		GND	"	Vcc		1.2	"
	ICCL	3005	53	5.5 V	5.5 V	5.5 V	5.5 V	5.5 V		"		5.5 V	5.5 V	5.5 V		5.5 V	**	Vcc		3.3	"
2	Same te	sts, terminal	conditions a	and limits a	as for sub	group 1, e	except T _C	= 125° C,	and V _{LC}	tests are o	omitted.										
3		sts, terminal																			
9	t _{PHL}	3003	54	IN	2.7 V	2.7 V	2.7 V	2.7 V	10	GND		2.7 V	2.7 V	2.7 V	OUT	2.7 V	5.0 V	1A to 1Y	2	17	ns
Tc = 25°C	SPILE .	Fig. 3	55	2.7 V	IN	"	"	"		"		"	"		"	2.7 V	"	1B to 1Y	"	"	"
10 - 20 0		"	56	"	2.7 V	"	"	"		"		"	"	"	"	IN	"	1C to 1Y	**	"	"
		"	57	"	2.1 V "	IN	"	"	OUT	"		"	"	"		2.7 V	"	2A to 2Y	**	"	"
		"	58	"	"	2.7 V	IN		"	"		"	"			2.1 V	"	2B to 2Y	"	"	"
			59	"	"	2.7 V "	2.7 V	IN	"	"		"				"	"	2C to 2Y	**	"	"
			59 60	"	"	"	2.1 V	2.7 V		"	OUT	IN				"	"	3A to 3Y	"	"	"
			61	"	"	"		2.1 V		"	"	2.7 V	IN			"	"	3A to 3Y 3B to 3Y	"	"	"
			62	"	"	"				"	"	∠./ V	2.7 V	IN		"	"		"	"	"
		"		IN	"	"				"		"	2.7 V	2.7 V	OUT	"		3C to 3Y	"	15	
	t _{PLH}		63			"	"			"		"		2.7 V	001	"	"	1A to 1Y	**	15	ns "
			64	2.7 V	IN					"		"					"	1B to 1Y		"	"
			65		2.7 V				0.UT	"						IN	"	1C to 1Y		"	"
			66			IN			OUT	"						2.7 V	"	2A to 2Y	"	"	"
			67			2.7 V	IN			"							"	2B to 2Y		"	"
			68				2.7 V "	IN		"	0.UT						"	2C to 2Y	"	"	"
			69					2.7 V		"	OUT	IN					"	3A to 3Y		"	"
			70	"		"				"		2.7 V	IN				"	3B to 3Y	"	"	"
			71	"		"							2.7 V	IN				3C to 3Y			
10	t _{PHL}		72	IN						"			"	2.7 V	OUT	"	"	1A to 1Y	"	24	ns "
Tc = 125°C		"	73	2.7 V	IN	"								"	"			1B to 1Y			
			74	"	2.7 V	"		"		"		"	"	"	"	IN	"	1C to 1Y	"	"	"
			75	"	"	IN		"	OUT	"		"	"	"		2.7 V	"	2A to 2Y	"	"	"
			76	"	"	2.7 V	IN	"	"	"		"	"			"	"	2B to 2Y	**	"	"
			77	"	"	"	2.7 V	IN	"	"		"	"			"	"	2C to 2Y	**	"	"
		"	78	"	"	"	"	2.7 V		"	OUT	IN	"	"		"	"	3A to 3Y	"	"	"
		"	79	"	"	"		"		"	"	2.7 V	IN			"	"	3B to 3Y	"	"	"
		"	80	"	"	"	"	"		"	"	"	2.7 V	IN		"	"	3C to 3Y	"	"	"
	t _{PLH}	"	81	IN	"	-	-	"						2.7 V	OUT	"		1A to 1Y	"	20	ns
		"	82	2.7 V	IN	"	"	"		"		"	"	"	"	"	"	1B to 1Y	"	"	"
		"	83	"	2.7 V	"	"	"		"		"	"	"	"	IN	"	1C to 1Y	**	"	"
		"	84	"	"	IN	-	-	OUT	"		"	"	"		2.7 V	"	2A to 2Y	"	"	"
		"	85	"	"	2.7 V	IN	"	"	"		"	"	"		"	"	2B to 2Y	**	"	"
		"	86	"	"	"	2.7 V	IN	"	"		"	"	"		"	"	2C to 2Y	**	"	"
		"	87	"	"	"	-	2.7 V		"	OUT	IN	"	"		"	"	3A to 3Y	**	"	"
		"	88	"	"	"	"	"		"	"	2.7 V	IN	"		"	"	3B to 3Y	**	"	"
		"	89	"	"	"	"	"		"	"	2.7 V	2.7 V	IN		"	"	3C to 3Y	"	"	"
11	Same te	sts, terminal		and limits a	as for sub-	aroup 10	excent T/	· = -55° €		•			•								
••	Sume le		00110110113			yioup 10,	oncopi I(,_ 00 0	<i>.</i> .												

TABLE III. <u>Group A inspection for device type 05</u> – Continued. Terminal conditions (pins not designated may be high ≥ 2.0 V or low ≤ 0.7 V or open).

TABLE III. Group A inspection for device type 05 - Continued. Terminal conditions (pins not designated may be high ≥ 2.0 V or low ≤ 0.7 V or open).

 $\underline{1}/~$ For case X and 2, pins not referenced are NC. $\underline{2}/~$ I_{IL} limits in μA are as follows:

Measured terminal			Min/max lim	its for circuit		
	А	В	С	D	E	F
1A, 1B, 1C, 2A, 2B, 2C	-120/-360	-30/-300	-150/-380	-150/-380	-160/-400	-100/-340
1C, 2C, 3C						

3/ Ios limits for circuit C are: -20/-100 mA; for circuit B are: -30/-300 mA: for circuits A, D, E, and F: -15/-100 mA.

			Cases	1	2	3	4	5	6	7	8	<u>2 2.0 V C</u> 9	10).7 V or c 11	12	13	14				<u> </u>
		MIL-STD-	A,B,C,D	1	2	5	4	5	0	'	0	9	10		12	15	14				
bgroup	Symbol	883	Case <u>1</u> /	2	3	4	6	8	9	10	12	13	14	16	18	19	20	Measured	Lim	its	Uni
		method	X and 2	4.0	1B	0.4	2B		01/		21/	0.4	3B	20	1Y	1C		terminal	Min		-
4	M	2007	Test no.	1A 2.0 V	2.0 V	2A GND	2B GND	2C GND	2Y	GND	3Y	3A GND	3B GND	3C GND			V _{CC} 4.5 V	41/	Min	Max	Va
1	Vol	3007	1 2	GND	GND	2.0 V	2.0 V	2.0 V	4 mA	GND "		GND	GND	GND	4 mA	2.0 V GND	4.5 V "	1Y 2Y		0.4	V d
c = 25°C				GND	GND	GND	GND	GND	4 IIIA	"	4 mA	2.0 V	2.0 V	2.0 V		GND	"	21 3Y		66	"
	1		3	0.7 V	5.5 V	5.5 V	5.5 V	5.5 V		"	4 MA	2.0 V 5.5 V	2.0 V 5.5 V	2.0 V 5.5 V	5.5 V	5.5 V		31 1Y		100	
	I _{CEX}		5	5.5 V	0.7 V	3.3 V	J.J V "	3.3 V		"		3.3 V	3.3 V	5.5 V	J.J V "	5.5 V	"	1Y		100	μA "
			6	3.3 V	5.5 V	"	"	"		"			"	"	"	0.7 V	"	1Y			"
			7	"	0.0 V	0.7 V	"	н	5.5 V	"		"	"	"		5.5 V	66	2Y		"	"
			8	"		5.5 V	0.7 V	"	0.0 v "	"		"	"	"		0.0 V	"	2Y		"	"
			9	"	"	0.0 V	5.5 V	0.7 V	"	"		"	"	"		"	**	2Y		"	"
			10	"		"	"	5.5 V		"	5.5 V	0.7 V	"	"		"	66	3Y		"	"
			11	"		"	"	"		"	"	5.5 V	0.7 V	"		"	"	3Y		"	"
			12	"	"	"	"	"		"	"	"	5.5 V	0.7 V		"	"	3Y		"	"
	VIC		13	-18 mA						"							"	1A		-1.5	V do
			14		-18 mA					"							**	1B		**	"
			15							"						-18 mA	"	1C		**	"
			16			-18 mA				"							"	2A		"	"
			17				-18 mA			"							"	2B		"	"
			18					-18 mA		ű							"	2C		"	"
			19							"		-18 mA	10.1				"	3A		"	"
			20							"			-18 mA	40 4			"	3B		"	"
	-	0040	21	0714						"				-18 mA				3C			
	Інт	3010	22 23	2.7 V GND	GND 2.7 V	GND "	GND "	GND		"		GND "	GND "	GND		GND GND	5.5 V "	1A 1B		20 "	μA "
			23	GND "	GND	"	"	"		"		"	"	"		2.7 V	"	1D 1C		**	"
			24	"	GND "	2.7 V	"	"		"		"	"	"		GND	"	2A		"	"
			26	"	"	GND	2.7 V	"		"		"	"	"		"	"	2R 2B		**	"
			27	"	"	"	GND	2.7 V		"		"	"	"		**	66	2C		**	**
			28	"	"	"	"	GND		"		2.7 V	"	"		"	"	3A		"	"
			29	"	"	"	"	"		"		GND	2.7 V	"		"	"	3B		"	"
			30	"	"	"	"	"		"		"	GND	2.7 V		"	**	3C		**	"
	I _{IH2}	"	31	5.5 V	"	"	"	"		"		"	"	GND		"	"	1A		100	μA
			32	GND	5.5 V	-	-	=		"		"	**	"		-	66	1B		**	**
			33	"	GND			н		"		"	"	"		5.5 V	**	1C		**	**
			34	"	"	5.5 V		-		"		"	"	"		GND	**	2A		"	"
			35	"	"	GND	5.5 V			"		"	"	"		"	"	2B		"	"
			36	"	"	"	GND	5.5 V		"		"		"		**	"	2C		"	"
			37					GND		"		5.5 V					"	3A		"	"
			38	"	"			"		"		GND "	5.5 V GND	E E V			"	3B		"	"
		3009	39 40	0.4 V	5.5 V	5.5 V	5.5 V	5.5 V		"		5.5 V	5.5 V	5.5 V "		5.5 V	"	3C 1A	2/	2/	"
	I _{I L}	5009	40	0.4 V 5.5 V	0.4 V	0.0 V	0.0 V	5.5 V "		"		5.5 V "	5.5 V "	"		5.5 V 5.5 V	"	1A 1B	<u>Z/</u> "	<u>_/</u> "	"
		"	41	0.0 V "	0.4 V 5.5 V	"	"	"		"		"	"	"		0.4 V	"	1D 1C	"	**	"
		"	42	"	"	0.4 V	"			"	-	"	"	"		5.5 V	"	2A	"	"	"
			44	"	"	5.5 V	0.4 V	"		**		"	"	"		"	"	2B	"	**	"
		"	45	"	"	"	5.5 V	0.4 V		"		"	"	"		**	"	2C	"	**	**
		"	46	"	"	"	"	5.5 V		"		0.4 V	"	"		"	"	3A	"	"	"
			47	"	"	"	**	"		"		5.5 V	0.4 V	"		"	**	3B	"	**	"
			48	"	"	"	66	"		"		5.5 V	5.5 V	0.4 V		"	"	3C	"	**	"
							cept T _c =	1050.0													-

TABLE III.	Group A inspection for device type 06.
Terminal conditions (pins not	designated may be high > 2.0 V or low < 0.7 V or open)

See footnotes at end of device type 06

					Ierr	minal cor	naitions (pins not	designa	ted may	be nign	≥ 2.0 V C	or low ≤ 0	0.7 V Or C	ppen).						
		MIL-STD-	Cases A,B,C,D	1	2	3	4	5	6	7	8	9	10	11	12	13	14				
Subgroup	Symbol	-	Case 1/	2	3	4	6	8	9	10	12	13	14	16	18	19	20	Measured	Lim	nits	Unit
Cubgroup	Cymbol	method	X and 2	-	Ŭ		Ŭ	Ŭ	Ŭ	10		10		10	10	10	20	terminal	2	into	onin
		method	Test no.	1A	1B	2A	2B	2C	2Y	GND	3Y	ЗA	3B	3C	1Y	1C	V _{CC}	tonnai	Min	Max	
1	I _{ссн}	3005	49	GND	GND	GND	GND	GND	21	GND	01	GND	GND	GND		GND	5.5 V	Vcc		1.4	mA
Tc = 25°C	ICCL	3005	50	5.5 V	5.5 V	5.5 V	5.5 V	5.5 V		"		5.5 V	5.5 V	5.5 V		5.5 V	"	Vcc		3.3	mA
9	t _{PHI}	3003	51	IN	2.7 V	2.7 V	2.7 V	2.7 V		-		2.7 V	2.7 V	2.7 V	OUT	2.7 V	5.0 V	1A to 1Y	2	36	ns
Tc = 25°C	SPILE	Fig. 3	52	2.7 V	IN	"	"	"		"		"		"	"	2.7 V	"	1B to 1Y	"	"	"
			53	"	2.7 V	"	"	"		"		"	"	н	"	IN	"	1C to 1Y	"	"	"
			54	"	"	IN	"	"	OUT	"		"	"	п		2.7 V	"	2A to 2Y	"	"	"
			55	"	"	2.7 V	IN	"	"	"		"	"	н		"	"	2B to 2Y	66	"	"
			56	"	"	2.7 V "	2.7 V	IN	"	"		"	"	н		н	"	2C to 2Y	"	"	"
			57	"	"	"	"	2.7 V		"	OUT	IN	"	н		"	"	3A to 3Y	66	"	"
			58	"	"	"	"	2.7 V		"	"	2.7 V	IN	"		"	"	3B to 3Y	66	"	"
			59	"	"	"	"	"		"	"	2.1 V "	2.7 V	IN		"	"	3C to 3Y	"	"	"
	t		60	IN	"	"	"	"				"	2.7 V	2.7 V	OUT	"	"	1A to 1Y	"	40	ns
	t _{PLH}		61	2.7 V	IN		"			"				Z.7 V	"		"	1B to 1Y	"	40 "	"
			62	2.7 V	2.7 V		"			"				"	"	IN	"	1C to 1Y	"	"	"
			63	"	2.1 V "	IN	"	"	OUT	"				"		2.7 V	"	2A to 2Y	"	"	"
			64		"	2.7 V	IN	"	"	"		"		"		2.7 V	"	2B to 2Y	"	"	"
			65		"	2.7 V "	2.7 V	IN		"		"		"		"	"	2C to 2Y	"	"	"
			66		"	"	2.7 V	2.7 V		"	OUT	IN		п		"	"	3A to 3Y	**	"	"
			67		"	"	"	2.7 V		"	"	2.7 V	IN			"	"	3B to 3Y	"	"	"
			68	"	"	"	"	"		"	"	2.7 V	2.7 V	IN			"	3C to 3Y	**	"	"
10	+	3003	69	IN	"	"	"	"				2.7 V	2.7 V 2.7 V	2.7 V	OUT	"	"	1A to 1Y	2	55	"
Tc = 125°C	t _{PHL}	5003 Fig. 3	70	2.7 V	IN		"	"		"		2.7 V	2.7 V	2.7 V	"		"	1B to 1Y	"	- 55 "	"
$10 = 125^{\circ}$		гig. 5 "	70	2.7 V	2.7 V	"	"			"					"	IN	"		66	"	"
			71	"	2.7 V	IN	"	"	OUT	"				"		2.7 V	"	1C to 1Y 2A to 2Y	"	"	"
			72	"	"	2.7 V	IN	"	001	"						2.7 V	"	2A to 2Y 2B to 2Y	"	"	"
			73	"	"	2.7 V	2.7 V			"				"		"	"		"	"	"
			74	"	"		2.7 V	IN 2.7 V		"	OUT	IN		"			"	2C to 2Y 3A to 3Y	"	"	"
			75	"	"	"		2.7 V		"	001	2.7 V	IN			"	"	3A to 3Y 3B to 3Y	"	**	"
			76		"					"		2.7 V	2.7 V			"	"		"	"	"
	4	"			"		"						2.7 V	IN	OUT	"		3C to 3Y	"		"
	t _{PLH}		78	IN 2.7 V	IN					"				2.7 V	OUT "		"	1A to 1Y	"	60 "	"
			79	2.7 V						"							"	1B to 1Y	"	"	"
			80		2.7 V					"						IN	"	1C to 1Y	"	"	"
			81			IN			OUT	"						2.7 V	"	2A to 2Y	"	"	"
			82			2.7 V	IN			"							"	2B to 2Y		"	"
			83	"			2.7 V "	IN		"	0.17						"	2C to 2Y	"	"	"
			84	"	"		"	2.7 V		"	OUT	IN		"			"	3A to 3Y	"	"	"
			85									2.7 V	IN					3B to 3Y			
		"	86	"	"	"	"	"		"	"	2.7 V	2.7 V	IN		"	"	3C to 3Y	66	"	"
11	Same te	ests, terminal	conditions a	and limits a	as for sub	group 10,	except T _c	c = −55° C													

TABLE III. <u>Group A inspection for device type 06</u> – Continued. Terminal conditions (pins not designated may be high ≥ 2.0 V or low ≤ 0.7 V or open).

 $\underline{1}$ / For case X and 2, pins not referenced are NC. $\underline{2}$ / $I_{\rm IL}$ limits in μ A are as follows:

Measured terminal			Min/max lim	its for circuit		
	А	В	С	D	E	F
1A, 1B, 1C, 2A, 2B, 2C, 3A, 3B, 3C	-160/-400	-30/-300	-150/-380	-160/-400	-150/-380	-150/-380

			-	-					designat												
		MIL-STD-	Cases A,B,C,D	1	2	3	4	5	6	7	8	9	10	11	12	13	14				1
Ibgroup	Symbol		Case <u>1</u> / X and 2	2	3	4	6	8	9	10	12	13	14	16	18	19	20	Measured terminal	Lim	iits	Unit
		methou	Test no.	1A	1B	NC	1C	1D	1Y	GND	2Y	2A	2B	NC	2C	2D	V _{CC}	terminar	Min	Max	
1	V _{OH}	3006	1	0.7 V	5.5 V	NO	5.5 V	5.5 V	-400 μA	GND	21	5.5 V	5.5 V	NO	5.5 V	5.5 V	4.5 V	1Y	2.5 V	IVIAA	V
= 25°C	V OH	"	2	5.5 V	0.7 V		5.5 V	0.0 v "	- 4 00 μΛ	"		0.0 v "	0.0 V		0.0 V	0.0 V	4.5 V	1Y	2.5 V		"
= 25°C			3	5.5 V	5.5 V		0.7 V	"		"						"	"	1Y	"		
			4	"	5.5 V			0.7 V		"						"	"	1Y 1Y	"		
			5	"	"		5.5 V	5.5 V		"	4004	0.7 V	"			"		2Y	"		
			6	"	"			3.3 V		"	-400 μA	5.5 V				"	"	21 2Y	"		
			6 7	"	"		"	"		"	"	0.5 V	0.7 V 5.5 V		0.7 V		"	2 Y 2Y	"		
			8	"	"		"	"		"	"	"	5.5 V 5.5 V		0.7 V 5.5 V	0.7 V	"	2 Y 2Y	"		
	V	2007	9	2.0 V	2.0 V		2.0 V	2.0 V	4 mg A	"		GND	S.S V GND		GND	GND	"	1Y		0.4	
	V _{OL}	3007							4mA	"	4 mm A									-	
	V	3007	10 11	GND	GND		GND	GND		"	4mA	2.0 V	2.0 V		2.0 V	2.0 V		2Y 1A		0.4 -1.5	
	VIC		11	-18 mA	-18 mA					"								1A 1B		-1.5	
			12		-10 IIIA		-18 mA			"							н	1B 1C		п	
			13				-10 IIIA	-18mA		"							н	10 1D		п	
			14					-TomA		"		-18 mA						2A		"	
			15							"		-10 IIIA	-18 mA					2A 2B			"
			10							"			-10 IIIA		-18 mA			2D 2C			"
			17							"					-10 IIIA	-18 mA		20 2D		"	"
	l	3010	18	2.7 V	GND		GND	GND		"		GND	GND		GND	GND	5.5 V	1A		20	^
	I _{IH1}	3010	20	GND	2.7 V		GND	GND		"		GND	GND "		GND	GND "	5.5 V	1A 1B		20	μA "
			20	GND "	GND		2.7 V	"		"		"	"			"		1D 1C			
			21	"	GND		GND	2.7 V		"						"	"	10 1D			
			22	"	"		GND "	GND		"		2.7 V	"			"		2A		"	"
			23	"	"		"	GND "		"		GND	2.7 V				"	2A 2B			
			24	"	"		"	"		"		GND "	GND		2.7 V		"	2D 2C			
			26	"	"		"	"		"		"	UND "		GND	2.7 V		20 2D		"	
	l		20	5.5 V	"		"	"		"		"	"		GND "	GND		1A		100	
	I _{IH2}		27	GND	5.5 V		"	"		"			"			GND "		1A 1B		100	
			20	GND "	GND		5.5 V	"		"		"	"		"	"	"	1D 1C		"	"
			30	"	"		GND	5.5 V		"		"	"			"	"	10 1D		"	
			31	"	"		"	GND		"		5.5 V	"			"	"	2A		"	
			32	"	"		"	"		"		GND	5.5 V			"	"	2A 2B		н	"
			33	"	"		"	"		"		"	GND		5.5 V	н	"	2D 2C			
			34	"	"		"	"		"		"	GND		GND	5.5 V		20 2D		"	"
	IL	3009	35	0.4 V	5.5 V		5.5 V	5.5 V		"		5.5 V	5.5 V		5.5 V	"	"	1A	2/	2/	"
	·IL	"	36	5.5 V	0.4 V		5.5 V	"		"		"	"		"	"	"	1B	"	"	
			37	"	5.5 V		0.4 V	"		"		"	"		"	"	"	1C	"	"	"
			38	"	"		5.5 V	0.4 V		"		"	"		"	"	н	10 1D	"	п	"
			39	"	"		"	5.5 V		"		0.4 V	"		"	н	"	2A	"	н	"
			40	"	"		"	"		"		5.5 V	0.4 V		"	н	"	2B	"	н	"
			41	"	"		"	"		"		"	5.5 V		0.4 V	н	"	2C	"	н	"
			42	"	"		"	"		"		"	5.5 V		5.5 V	0.4 V	"	2D	"	н	"
	l _{os}	3011	43	GND	GND		GND	GND	GND	"							"	1Y	3/	3/	m/
	00	3011	44	-	-		-		-	"	GND	GND	GND		GND	GND	"	2Y	3/	3/	"
	I _{ссн}	3005	49	GND	GND		GND	GND		"	-	GND	GND		GND	GND	"	V _{cc}	-	0.8	"
		3005	50	5.5 V	5.5 V		5.5 V	5.5 V		"		5.5 V	5.5 V		5.5 V	5.5 V	"	Vcc		2.2	"
					s for subg													50			<u>ــــــــــــــــــــــــــــــــــــ</u>

See footnotes at end of device type 07.

					Term	inai con	aitions (oins not o	aesignati	ed may i	be nign ≥	2.0 V 0	r low ≤ 0 .	.7 V OF O	pen).						
		MIL-STD-	Cases A,B,C,D	1	2	3	4	5	6	7	8	9	10	11	12	13	14				
Subgroup	Symbol	883 method	Case <u>1</u> / X and 2	2	3	4	6	8	9	10	12	13	14	16	18	19	20	Measured terminal	Lim	nits	Unit
		mounou	Test no.	1A	1B	NC	1C	1D	1Y	GND	2Y	2A	2B	NC	2C	2D	Vcc		Min	Max	1
9	t _{PHL}	3003	47	IN	2.7 V		2.7 V	2.7 V	OUT	GND		2.7 V	2.7 V		2.7 V	2.7 V	5.0 V	1A to 1Y	2	17	ns
Tc = 25°C	1112	Fig. 3	48	2.7 V	IN		2.7 V	"	"	"		"	"		"	"	"	1B to 1Y	"	"	"
		"	49	"	2.7 V		IN	"	"	"		"	"		"	"	"	1C to 1Y	"	"	"
		"	50	"	"		2.7 V	IN	"	"		"	"		"	"	"	1D to 1Y	"	"	"
		"	51	"	"		"	2.7 V		"	OUT	IN	"		"	"	"	2A to 2Y	"	"	"
		"	52	"	"		"	"		"	"	2.7 V	IN		"	"	"	2B to 2Y	**	"	**
		"	53	"	"		"	"		"	"	"	2.7 V		IN	"	"	2C to 2Y	**	"	**
		"	54	"	"		"	"		"	"	"	"		2.7 V	IN	"	2D to 2Y	**	"	**
	t _{PLH}	"	55	IN	"			"	OUT	**		"	"		"	2.7 V	"	1A to 1Y	**	15	"
		"	56	2.7 V	IN					"		"	"		"	"	"	1B to 1Y	"	"	**
		"	57	"	2.7 V		IN	-		"		"	"		"	"	"	1C to 1Y	"	"	"
		"	58	"	"		2.7 V	IN		"		"	"		"	"	"	1D to 1Y	"	"	"
		"	59	"	"		"	2.7 V		"	OUT	IN	"		"	"	"	2A to 2Y	"	"	"
		"	60	"	"			-		"	"	2.7 V	IN		"	"	"	2B to 2Y	"	"	"
		"	61	"	"		-			"	"	"	2.7 V		IN	"	"	2C to 2Y	"	"	"
		"	62	"	"		"	"		"	"	"	"		2.7 V	IN	"	2D to 2Y	**	"	"
10	t _{PHL}	3003	63	IN	"			"	OUT	-		"	"		"	2.7 V	5.0 V	1A to 1Y	"	24	"
Tc = 125°C		Fig. 3	64	2.7 V	IN					"		"	"		"	"	"	1B to 1Y	"	"	**
		"	65	"	2.7 V		IN	"	"	"		"	"		"	"	"	1C to 1Y	"	"	**
		"	66	"	"		2.7 V	IN	"	"		"	"		"	"	"	1D to 1Y	"	"	**
		"	67	"	"		"	2.7 V		"	OUT	IN	"		"	"	"	2A to 2Y	"	"	"
		"	68	"	"		"	"		"	"	2.7 V	IN		"	"	"	2B to 2Y	"	"	"
		"	69	"	"		"	"		"	"	"	2.7 V		IN	"	"	2C to 2Y	"	"	"
		"	70	"	"		"	"		"	"	"	"		2.7 V	IN	"	2D to 2Y	"	"	"
	t _{PLH}	"	71	IN	"		"	"	OUT	"		"	"		"	2.7 V	"	1A to 1Y	"	20	"
		"	72	2.7 V	IN		"	"	"	"		"	"		"	"	"	1B to 1Y	**	"	"
		"	73	"	2.7 V		IN	"	"	"		"	"		"	"	"	1C to 1Y	"	"	"
		"	74	"	"		2.7 V	IN	"	"		"	"		"	"	"	1D to 1Y	**	"	"
		"	75	"	"		"	2.7 V		"	OUT	IN	"		"	"	"	2A to 2Y	**	"	"
		"	76	"	"		"	"		"	"	2.7 V	IN		"	"	"	2B to 2Y	"	"	"
		"	77	"	"		"	"		"	"	"	2.7 V		IN	"	"	2C to 2Y	**	"	"
		"	78	"	"		"	"		"	"	"	"		2.7 V	IN	"	2D to 2Y	**	"	"
11	Same tes	sts, terminal c	conditions a	nd limits a	s for subgi	oup 10, e	except T _C	= -55° C.													

TABLE III. <u>Group A inspection for device type 07</u> – Continued. Terminal conditions (pins not designated may be high ≥ 2.0 V or low ≤ 0.7 V or open).

 $\underline{1}/~$ For case X and 2, pins not referenced are NC. $\underline{2}/~$ I_{IL} limits in μA are as follows:

Measured terminal			Min/max lim	its for circuit		
	А	В	С	D	Ш	F
1A, 1B, 1C, 1D,	-120/-360	-30/-300	-160/-400	-120/-360	-150/-380	-100/-340
2A, 2B, 2C, 2D						

3/ I_{os} limits for circuit C: -20/-100 mA; for circuits A, B, D, E, and F: -15/-100 mA.

	1		-				nditions (
		MIL-STD-	Cases A,B,C,D	1	2	3	4	5	6	7	8	9	10	11	12	13	14				
bgroup	Symbol	883	Case <u>1</u> /	2	3	4	6	8	9	10	12	13	14	16	18	19	20	Measured	Lim	its	Uni
		method	X and 2	4.4	40	NC	40	1D	41/		2Y	0.4	2B	NO		2D		terminal	N.41-	Maria	
4		0007	Test no.	1A	1B	NC	1C		1Y	GND	2 Y	2A	GND	NC	2C GND		V _{CC}	414	Min	Max	V
1	V _{OL}	3007	1	2.0 V	2.0 V GND		2.0 V GND	2.0 V GND	4mA	GND	4 mm A	GND	-			GND	4.5 V	1Y 2Y		0.4	V
; = 25°C		3007	2	GND					5 5 1/		4mA	2.0 V	2.0 V		2.0 V	2.0 V		2Y 1Y		0.4	
	ICEX		3	0.7 V	5.5 V		5.5 V	5.5 V	5.5 V	"		5.5 V	5.5 V		5.5 V	5.5 V				100	μA "
			4	5.5 V	0.7 V		5.5 V			"			"					1Y		"	
			5		5.5 V		0.7 V											1Y			
			6				5.5 V	0.7 V		"	5 5 1 (0714						1Y			
			7					5.5 V		"	5.5 V	0.7 V						2Y			
			8							"		5.5 V	0.7 V					2Y			
			9							"			5.5 V		0.7 V	0714		2Y			
			10							"					5.5 V	0.7 V		2Y			
	V _{IC}		11	-18 mA	40.4					"								1A		-1.5	V
			12		-18 mA		40.4			"								1B			
			13 14				-18 mA	10mm A		"					1			1C 1D			
			14					-18mA		"		10 1						2A			"
			15							"		-18 mA	-18 mA				"	2A 2B			"
			16							"			-18 MA		-18 mA		"	2B 2C		"	
			17							"					-18 MA	10		20 2D			"
		3010	18	2.7 V	GND		GND	GND		"		GND	GND		GND	-18 mA GND	5.5 V	2D 1A		20	
	I _{IH1}	3010	20	GND	2.7 V		GND	GND		"		GND	GND		GND	GND	5.5 V	1A 1B		20	μ/
			20	GND			2.7 V			"								1B 1C			
			21	"	GND "		GND	2.7 V		"			"		"			10 1D			
			22	"			GND "	GND		"		2.7 V	"		"		"	2A		"	"
			23	"			"	GND "		"		GND	2.7 V				"	2A 2B			"
			24	"			"			"		GND "	GND		2.7 V		"	2D 2C			
			25	"			"			"			GND "		GND	2.7 V	"	20 2D			"
	1	"	20	5.5 V	"		"	"		"		"	"		GND "	GND		1A		100	"
	I _{IH2}		28	GND	5.5 V		"	"		"		"	"		"	UND "		1A 1B		"	"
			20	GND "	GND		5.5 V	"		"		"	"		"			1D 1C		"	"
			30	"	UND "		GND	5.5 V		"		"	"		"			10 1D		"	"
			30	"	"		GND "	GND		"		5.5 V	"		"			2A		"	"
			32	"	"		"	GND "		"		GND	5.5 V		"	"	"	2A 2B			"
			33	"	"		"	"		"		"	GND		5.5 V	"	"	2D 2C		"	"
			34	"	"		"	"		**		"	GND		GND	5.5 V	"	20 2D		"	"
	IIL	3009	35	0.4 V	5.5 V		5.5 V	5.5 V		"		5.5 V	5.5 V		5.5 V	J.J V	"	1A	2/	2/	
	٩L	"	36	5.5 V	0.4 V		5.5 V	0.0 V "		"		0.0 V "	0.0 v "		0.0 V	"	"	1/X 1B	<u>-</u>	<u>_</u>	"
			37	"	5.5 V		0.4 V	"		"		"	"		"	"		1C	"	"	"
			38	"	"		5.5 V	0.4 V		"		"	"		"	"		1D	"	"	"
		"	39	"	"		"	5.5 V		"		0.4 V	"		"	"	"	2A	"	"	"
			40	"	"		"	"		"		5.5 V	0.4 V		"	"	"	2B	"	"	"
			41	"	"		"	"		"		"	5.5 V		0.4 V	"	"	2D 2C	"	"	"
			42	"	"		"	"		"		"	5.5 V		5.5 V	0.4 V	"	20 2D	"	"	"
	ICCL	3005	43	"	"		"	"		"		"	"		5.5 V	5.5 V	"	V _{CC}		2.2	m
	Іссн	3005	44	GND	GND		GND	GND		"		GND	GND		GND	GND	"	Vcc		0.8	m
	·UUN					·		125° C, a				0.10	0.10		0.10	0.10				0.0	

TABLE III. <u>Group A inspection for device type 08</u>. Terminal conditions (pins not designated may be high ≥ 2.0 V or low ≤ 0.7 V or open).

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See footnotes at end of device type 08.

					Term	inal con	aitions (p	Sins not o	Jesignati	eu may i	be nign ∠	2.0 V 0	r low ≤ 0 .	7 0 0 0	pen).						
		MIL-STD-	Cases A,B,C,D	1	2	3	4	5	6	7	8	9	10	11	12	13	14				
Subgroup	Symbol	883 method	Case <u>1</u> / X and 2	2	3	4	6	8	9	10	12	13	14	16	18	19	20	Measured terminal	Lim	nits	Unit
			Test no.	1A	1B	NC	1C	1D	1Y	GND	2Y	2A	2B	NC	2C	2D	Vcc		Min	Max	
9	t _{PHL}	3003	45	IN	2.7 V	-	2.7 V	2.7 V	OUT	GND		2.7 V	2.7 V		2.7 V	2.7 V	5.0 V	1A to 1Y	2	36	ns
Tc = 25°C		Fig. 3	46	2.7 V	IN		2.7 V	"	-	"		"	"		"	"	**	1B to 1Y	"	"	"
		"	47	"	2.7 V		IN	"	"	"		"	"		"	"	"	1C to 1Y	"	"	"
		"	48	"	"		2.7 V	IN	-	"		"	"		"	"	**	1D to 1Y	"	"	"
		"	49	"	"		-	2.7 V		"	OUT	IN	"		"	"	**	2A to 2Y	"	"	"
		"	50	"	"		н	"		"	"	2.7 V	IN		"	"	"	2B to 2Y	"	"	"
		"	51	"	"		"	"		**	"	"	2.7 V		IN	"	"	2C to 2Y	**	"	66
		"	52	"	"		"	"		**	"	"	"		2.7 V	IN	"	2D to 2Y	**	"	66
	t _{PLH}	"	53	IN	"		-	-	OUT	"		"	"		"	2.7 V	"	1A to 1Y	"	40	"
		"	54	2.7 V	IN		=	-	=	"		"	"		"	"	"	1B to 1Y	"	-	"
		"	55	"	2.7 V		IN		=	"		"	"		"	"	"	1C to 1Y	"	"	"
		"	56	"	"		2.7 V	IN	-	"		"	"		"	"	**	1D to 1Y	**	"	"
		"	57	"	"		=	2.7 V		"	OUT	IN	"		"	"	"	2A to 2Y	"	"	"
		"	58	"	"			"		"	"	2.7 V	IN		"	"	"	2B to 2Y	**	"	"
		"	59	"	"			"		"	"	"	2.7 V		IN	"	"	2C to 2Y	"	"	"
		"	60		"			"		"	"	"			2.7 V	IN	"	2D to 2Y	"	"	"
10	t _{PHL}	"	61	IN	"			"	OUT	-		"	"		"	2.7 V	"	1A to 1Y	"	55	"
Tc = 125°C		"	62	2.7 V	IN		"	"	"	"		"	"		"	"	"	1B to 1Y	**	"	"
		"	63	"	2.7 V		IN	"	"	"		"	"		"	"	"	1C to 1Y	"	"	"
		"	64		"		2.7 V	IN	"	"		"			"		"	1D to 1Y	"	"	"
		"	65	"	"			2.7 V		"	OUT	IN	"		"	"	"	2A to 2Y	"	"	"
		"	66		"			"		"	"	2.7 V	IN		"	"	"	2B to 2Y	"	"	"
		"	67		"			"		"	"	"	2.7 V		IN	"	"	2C to 2Y	"	"	"
		"	68		"			"		"	"	"	"		2.7 V	IN	"	2D to 2Y	"	"	"
	t _{PLH}	"	69	IN	"		"	"	OUT	"		"	"		"	2.7 V	"	1A to 1Y	"	60	"
		"	70	2.7 V	IN		"	"	"	"		"			"	"	"	1B to 1Y	"		"
		"	71	"	2.7 V		IN	"	"	"		"	"		"	"	"	1C to 1Y	"	"	"
		"	72	"	"		2.7 V	IN	"	"		"	"		"	"	"	1D to 1Y	"	"	"
		"	73		"			2.7 V		"	OUT	IN	"		"	"	"	2A to 2Y	"	"	"
		"	74		"			"		**	"	2.7 V	IN		"	"	"	2B to 2Y	"	"	"
		"	75		"			"		"	"	"	2.7 V		IN	"	"	2C to 2Y	"	"	"
		"	76	"	"			"		"	"	"	2.7 V		2.7 V	IN	"	2D to 2Y	"	"	"
11	Same tes	sts, terminal c	conditions a	nd limits as	s for subgr	oup 10, e	except T _C	= -55° C.													

TABLE III.	Group A inspection for device type 08 – Continued.
Terminal conditions (r	ins not designated may be high > 2.0 V or low < 0.7 V or open)

 $\underline{1}/~$ For case X and 2, pins not referenced are NC. $\underline{2}/~$ I_{IL} limits in μA are as follows:

Measured terminal	Min/max limits for circuit									
	Α	В	С	D	E	F				
1A, 1B, 1C, 1D,	-160/-400	-30/-300	-160/-400	-200/-440	-150/-380	-120/-360				
2A, 2B, 2C, 2D										

						minal co	nditions (pins not	designa	ted may		≥ 2.0 V C	or low ≤ 0).7 V or o	pen).						
		MIL-STD-	Cases A,B,C,D	1	2	3	4	5	6	7	8	9	10	11	12	13	14				
ubgroup	Symbol	883	Case <u>1</u> /	2	3	4	6	8	9	10	12	13	14	16	18	19	20	Measured	Lin	nits	Unit
		method	X and 2				_		-	OND	V	NIO	NIC	0		NO		terminal			
-		0000	Test no.	A	B	C	D	E	F	GND	Y	NC	NC	G	H	NC	V _{CC}	Y	Min	Max	V
1	V _{OH}	3006	1	0.7 V	5.5 V	5.5 V	5.5 V	5.5 V	5.5 V	GND	-400 μA			5.5 V	5.5 V		4.5 V	Ŷ	2.5 V		V
: = 25°C			2	5.5 V	0.7 V	5.5 V				"											
			3		5.5 V	0.7 V				"	"										
			4			5.5 V	0.7 V			"											
			5				5.5 V	0.7 V	071/	"											
			6 7					5.5 V	0.7 V	"				071/							
					"			"	5.5 V	"	"			0.7 V	071/						
	V	3007	8	2.0 V	2.0 V	2.0 V	2.0 V	2.0 V	5.5 V	"	4 mA			5.5 V 2.0 V	0.7 V 2.0 V		"			0.4	
	V _{OL} V _{IC}	3007	9 10	-18 mA	2.0 V	2.0 V	2.0 V	2.0 V	2.0 V	"	4 MA			2.0 V	2.0 V			A		-1.5	
	VIC		10	-16 MA	-18 mA					"								B		-1.5	
			12		-10 IIIA	-18 mA				"								C			
			12			-10 IIIA	-18 mA			"								D			
			13				-10 IIIA	-18 mA		"							"	E			
			14					-10 IIIA	-18 mA	"							"	F		"	
			16						-10 11/4	"				-18 mA			"	G		"	"
			17							"				-10111A	-18 mA		"	H		"	"
	I _{IH1}	3010	18	2.7 V	GND	GND	GND	GND	GND	"				GND	GND		5.5 V	A		20	μA
	UH1	3010	10	GND	2.7 V	GND	"	"	"	"				"	"		0.0 V	B		20	μ,
			20	"	GND	2.7 V	"	"	"	"				"	"		"	C		"	
			20	"	"	GND	2.7 V	"	"	"				"	"		"	D		"	
			22	"	"	"	GND	2.7 V	"	"				"	"		"	E		"	
			23	"	"	"	"	GND	2.7 V	"				"	"		"	F		"	
			24	"	"	"	"	"	GND	"				2.7 V	"		"	G		"	
			25	"	"	"	"	"	"	"				GND	2.7 V		"	Ĥ		"	"
	I _{IH2}	"	26	5.5 V	"	"	"	"	"	"				"	GND		"	A		100	"
	1112		27	GND	5.5 V	"	"	"	"	"				"	"		"	B		"	"
			28	"	GND	5.5 V	"	"	"	"				"	"		"	C		"	"
			29	"	"	GND	5.5 V	"	"	"				"	"		"	D		"	"
			30	"	"		GND	5.5 V	"	"				"	"		"	E		"	"
			31	"	"		"	GND	5.5 V	"				"	"		"	F		"	"
			32	"	"		"	"	GND	"				5.5 V	"		"	G		"	"
		"	33	"	"		"		GND	"				GND	5.5 V		"	Н		"	"
	I	3009	34	0.4 V	5.5 V	5.5 V	5.5 V	5.5 V	5.5 V	"				5.5 V			"	A	2/	2/	"
			35	5.5 V	0.4 V	5.5 V	"	"	"	"				"	"		"	В	"	"	
		"	36	"	5.5 V	0.4 V	"	"	"	"				"	"		"	С	"	"	"
		"	37	-	"	5.5 V	0.4 V	=	-	"				"	"		"	D	=		-
		"	38	-	"	"	5.5 V	0.4 V	"	"				"	=		"	E	=	"	
		"	39	-	"	-	"	5.5 V	0.4 V	"				"	=		"	F	=	"	"
		"	40	"	"	"	"	"	5.5 V	"				0.4 V	"		н	G	"	"	"
		"	41	"	"	"	"	"	5.5 V	"				5.5 V	0.4 V			Н		"	"
	l _{os}	3011	42	GND	GND	GND	GND	GND	GND	"	GND			GND	GND		н	Y	<u>3</u> /	<u>3</u> /	mA
	I _{ссн}	3006	43	GND	GND	GND	GND	GND	GND	"				GND	GND		"	Vcc		0.5	"
	IccL	3005	44	5.5 V	5.5 V	5.5 V	5.5 V	5.5 V	5.5 V	"				5.5 V	5.5 V		"	Vcc		1.1	"
			anditiona a	nd limite a	c for cuba		cept T _C =	125° C a	nd V to	ete aro o	mittod										

TABLE III. <u>Group A inspection for device type 09</u>. Terminal conditions (pins not designated may be high ≥ 2.0 V or low ≤ 0.7 V or open).

See footnotes at end of device type 09.

					Term	inai con	aitions (p	oins not o	designate	ed may t	be nign ≥	2.0 V 0	$10W \le 0$.7 V or op	ben).	-					
		MIL-STD-	Cases A,B,C,D	1	2	3	4	5	6	7	8	9	10	11	12	13	14				
Subgroup	Symbol	883 method	Case <u>1</u> / X and 2	2	3	4	6	8	9	10	12	13	14	16	18	19	20	Measured terminal	Lim	nits	Unit
			Test no.	А	В	С	D	E	F	GND	Y	NC	NC	G	Н	NC	Vcc		Min	Max	
9	t _{PHL}	3003	45	IN	2.7 V	2.7 V	2.7 V	2.7 V	2.7 V	GND	OUT			2.7 V	2.7 V		5.0 V	A to Y	2	28	ns
Tc = 25°C		Fig. 3	46	2.7 V	IN	2.7 V	"	"	"	"	"			"	"		"	B to Y	"	"	"
		"	47	"	2.7 V	IN	"	"	"	"	-			"	=		"	C to Y	"	"	"
		"	48	"	"	2.7 V	IN		"	"	"			"	"		"	D to Y	"	"	"
		"	49	"	"	"	2.7 V	IN	"	"	"			"	"		"	E to Y	**	"	"
		"	50	"	"		"	2.7 V	IN	"	"				"		**	F to Y	"	"	"
		"	51	"	"	"	"	"	2.7 V	"	"			IN	"		"	G to Y	"	"	"
		"	52	"	"	"	"	-	"	"	=			2.7 V	IN		"	H to Y	"	"	"
	t _{PLH}	"	53	IN	"	"	"		"	"	=			"	2.7 V		"	A to Y	"	20	"
		"	54	2.7 V	IN	"	"	-	-	"	=			"	=		"	B to Y	"	-	"
		"	55	"	2.7 V	IN	"		"	"	=			"	=		"	C to Y	"	"	"
		"	56	"	"	2.7 V	IN	"	"	"	"			"	"		"	D to Y	**	"	"
		"	57	"	"	"	2.7 V	IN	"	"	=			"	=		"	E to Y	"	"	"
		"	58	"	"	"	"	2.7 V	IN	"	"			"	"		"	F to Y	"	"	"
		"	59	"	"	"		"	2.7 V	"	"			IN	"		"	G to Y	"	"	"
		"	60	"	"	"	"	"	"	"				2.7 V	IN		"	H to Y	"	"	"
10	t _{PHL}	"	61	IN	"	"		"	"		"				2.7 V		"	A to Y	"	38	"
Tc = 125°C		"	62	2.7 V	IN	"	"	"	"	"				"	-		"	B to Y	"	"	"
		"	63	"	2.7 V	IN		"	"	"	"				"		"	C to Y	"	"	"
		"	64	"	"	2.7 V	IN	"	"	"	"			"	-		"	D to Y	**	"	"
		"	65	"	"	"	2.7 V	IN	"	"	"				"		"	E to Y	"	"	"
		"	66	"	"	"	"	2.7 V	IN	"	"			"	-		"	F to Y	"	"	"
		"	67	"	"	"		"	2.7 V	"	"			IN	"		"	G to Y	"	"	"
		"	68	"	"	"		"	"	"	"			2.7 V	IN		"	H to Y	"	"	"
	t _{PLH}	"	69	IN	"	"		"	"	"	"				2.7 V		"	A to Y	"	32	"
		"	70	2.7 V	IN	"	"	"	"	"				"			"	B to Y	**		"
		"	71	"	2.7 V	IN		"	"	"	"				"		"	C to Y	"	"	"
		"	72	"	"	2.7 V	IN	"	"	"	"			"	"		"	D to Y	"	"	"
		"	73	"	"	"	2.7 V	IN	"	"				"	"		ű	E to Y	"	"	"
		"	74	"	"	"	"	2.7 V	IN	"	-			"	"		"	F to Y	"	"	"
		"	75	"	"	"		"	2.7 V	"	"			IN	"		ű	G to Y	"	"	"
		"	76	"	"			"	2.7 V	"	"			2.7 V	IN		"	H to Y	"	"	"
11	Same tes	sts, terminal c	conditions a	nd limits as	s for subgi	roup 10, e	except T _C	= -55° C.													

TABLE III. <u>Group A inspection for device type 09</u> – Continued. Terminal conditions (pins not designated may be high ≥ 2.0 V or low ≤ 0.7 V or open).

 $\underline{1}/~$ For case X and 2, pins not referenced are NC. $\underline{2}/~$ I_{IL} limits in μA are as follows:

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Measured terminal		Min/max limits for circuit										
	А	В	С	D	E	F						
A, B, C, D, E, F, G, H	-0/-360	-30/-300	-160/-400	-160/-400	-150/380	-160/-400						

3/ Ios limits for circuit C: -20/-100 mA; for circuits A, B, D, E, and F: -15/-100 mA.

5. PACKAGING

5.1 <u>Packaging requirements.</u> For acquisition purposes, the packaging requirements shall be as specified in the contract or order (see 6.2). When actual packaging of materiel is to be performed by DoD personnel, these personnel need to contact the responsible packaging activity to ascertain requisite packaging requirements. Packaging requirements are maintained by the Inventory Control Point's packaging activity within the Military Department of Defense Agency, or within the Military Department's System Command. Packaging data retrieval is available from the managing Military Department's or Defense Agency's automated packaging files, CD-ROM products, or by contacting the responsible packaging activity.

6. NOTES

6.1 <u>Intended use.</u> Microcircuits conforming to this specification are intended for original equipment design applications and logistic support of existing equipment.

- 6.2 Acquisition requirements. Acquisition documents should specify the following:
 - a. Title, number, and date of the specification.
 - b. Complete part number (see 1.2).
 - c. Requirements for delivery of one copy of the quality conformance inspection data pertinent to the device inspection lot to be supplied with each shipment by the device manufacturer, if applicable.
 - d. Requirements for certificate of compliance, if applicable.
 - e. Requirements for notification of change of product or process to contracting activity in addition to notification to the qualifying activity, if applicable.
 - f. Requirements for failure analysis (including required test condition of method 5003 of MIL-STD-883), corrective action, and reporting of results, if applicable.
 - g. Requirements for product assurance options.
 - h. Requirements for special carriers, lead lengths, or lead forming, if applicable. These requirements shall not affect the part number. Unless otherwise specified, these requirements will not apply to direct purchase by or direct shipment to the Government.
 - j. Requirements for "JAN" marking.

6.3 <u>Superseding information</u>. The requirements of MIL-M-38510 have been superseded to take advantage of the available Qualified Manufacturer Listing (QML) system provided by MIL-PRF-38535. Previous references to MIL-M-38510 in this document have been replaced by appropriate references to MIL-PRF-38535. All technical requirements now consist of this specification and MIL-PRF-38535. The MIL-M-38510 specification sheet number and PIN have been retained to avoid adversely impacting existing government logistics systems and contractor's parts lists.

6.4 <u>Qualification</u>. With respect to products requiring qualification, awards will be made only for products which are, at the time of award of contract, qualified for inclusion in Qualified Manufacturers List QML-38535 whether or not such products have actually been so listed by that date. The attention of the contractors is called to these requirements, and manufacturers are urged to arrange to have the products that they propose to offer to the Federal Government tested for qualification in order that they may be eligible to be awarded contracts or purchase orders for the products covered by this specification. Information pertaining to qualification of products may be obtained from DSCC-VQ, 3990 E. Broad Street, Columbus, Ohio 43123-1199.

6.5 <u>Abbreviations, symbols, and definitions.</u> The abbreviations, symbols, and definitions used herein are defined in MIL-PRF-38535, MIL-HDBK-1331, and as follows:

GND	Ground zero voltage potential
l _{in}	Current flowing into an input terminal
V _{IC}	Input clamp voltage
V _{IN}	Voltage level at an input terminal

6.6 <u>Logistic support</u>. Lead materials and finishes (see 3.4) are interchangeable. Unless otherwise specified, microcircuits acquired for Government logistic support will be acquired to device class B (see 1.2.2), lead material and finish A (see 3.4). Longer length leads and lead forming shall not affect the part number.

6.7 <u>Substitutability.</u> The cross-reference information below is presented for the convenience of users. Microcircuits covered by this specification will functionally replace the listed generic-industry type. Generic-industry microcircuit types may not have equivalent operational performance characteristics across military temperature ranges or reliability factors equivalent to MIL-M-38510 device types and may have slight physical variations in relation to case size. The presence of this information shall not be deemed as permitting substitution of generic-industry types for MIL-M-38510 types or as a waiver of any of the provisions of MIL-PRF-38535.

Military device type	Generic-industry type
01	54LS00
02	54LS03
03	54LS04
04	54LS05
05	54LS10
06	54LS12
07	54LS20
08	54LS22
09	54LS30

6.8 <u>Manufacturers' designation</u>. Manufacturers' circuits, which form a part of this specification, are designated with an "X" as shown in table IV herein.

	Manufacturer									
Device	Circuit A	Circuit B	Circuit C	Circuit D	Circuit E	Circuit F				
type	Texas Instru-	Signetics	National	Raytheon	Motorola	Fairchild				
	ments Inc.	Corporation	Semiconductor	Company	Inc	Semiconductor				
			Corp							
01	Х	Х	Х	Х	Х	Х				
02	Х	Х	Х	Х	Х	Х				
03	Х	Х	Х	Х	Х	Х				
04	Х	Х	Х	Х	Х	Х				
05	Х	Х	Х	Х	Х	Х				
06	Х	Х	Х	Х	Х					
07	Х	Х	Х	Х	Х	Х				
08	Х	Х	Х	Х	Х	Х				
09	Х	X	Х	Х	Х	Х				

TABLE IV. Substitutability and manufacturers' designation.

6.9 <u>Changes from previous issue</u>. Asterisks are not used in this revision to identify changes with respect to the previous issue due to the extensiveness of the changes.

Custodians: Army - CR Navy - EC Air Force - 11 DLA - CC

Preparing activity: DLA - CC

(Project 5962-1945)

Review activities: Army - HD, MI, SM Navy - AS, CG, MC, SH, TD Air Force - 03, 19, 99

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3. DOCUMENT TITLE MICROCIRCUITS, DIGITAL, BIPOLAF	LOW-POWER SCHOTTKY TTL, AND	GATES, MONOLITHIC SILICON								
4. NATURE OF CHANGE (Identify paragraph)										
5. REASON FOR RECOMMENDATION										
6. SUBMITTER a. NAME (Last, First Middle Initial)	b. ORGANIZATION									
c. ADDRESS (Include Zip Code)	d. TELEPHONE (Incl. (1) Commercial (2) DSN (If applicable)	ude Area Code) 7. DATE SUBMITTED (YYYYMMDD)								
8. PREPARING ACTIVITY										
a. NAME Defense Supply Center, Columbus	b. TELEPHONE (Incl. (1) Commercial 614-									
c. ADDRESS (Include Zip Code) DSCC-VA P. O. Box 3990 Columbus, Ohio 43216-5000	Defense Standardiz 8725 John J. Kingm Fort Belvoir, Virginia Telephone (703)767	7-6888 DSN 427-6888								
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